

SERVICE MANUAL

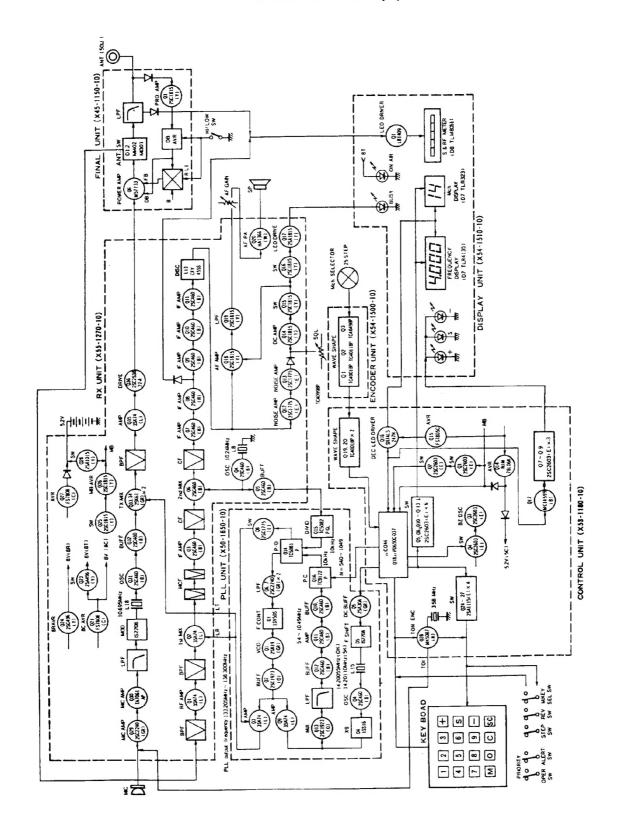
Model TR-7800



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BLOCK DIAGRAM (K)



2

RX Section (X55-1270-10)

The RF signal amplified by the front end dual gate MOS FET Q1 is applied through the helical resonator L3 to Q2 to obtain a 10.695 MHz IF signal.

The output of Q2 passes through the 2-element MCF (monolithic crystal filter to provide an excellent 2-signal characteristic. The IF signal amplified by Q3 is applied to Q6 to produce the 455 kHz 2nd IF signal. This signal is then amplified by Q7-11 and is applied to the ceramic discriminator L13. The output from Q8 (455 kHz amplifier) is fed to the LED level meter for an S meter signal.

The squelch circuit, composed of Q12-15, controls the AF circuit Q18. The busy lamp drive signal and scan busy stop signal (SS) are produced by Q16 and 17 and fed to the busy lamp circuit on the display unit and the scan circuit on the control unit.

The AF signal is amplified by Q18. This is fed to the power amplifier Q20 through the active LPF (low pass filter) Q19 and the AF gain control.

	Sym-	Condition		Rating				
ltem	bol (Ta = 25°C		MIN	TYP	MAX	Unit		
DC current with no input	la	Vin = 0	_	30.0	60.0	mA		
Gain in voltage	Gv	Vin = -50 dB	50.0	52.5	55.0	dB		
Output power	Po	THD = 10%	4.5	5.5	-	w		
Distortion	THD	Po = 0.5W		_	1.5	%		
Noise level WBN		Rg = 10 kΩ. 8W = 20 Hz ~ 20 kHz	-	-	2.0	mV		
Hum ratio	HR	f = 500 Hz	28.0	-	-	dB		
Voltage allowance with a shorted load		f = 500 Hz Vin = 10 mV. t = 5 sec.	16.0	-	-	v		

Г	Rank	1	2	3
	Gv (dB)	50.0 ~ 52.2	51.4 ~ 53.6	52.8 ~ 55.0

Table 1. HA1366W (RX Unit: Q20)

Item	Rating
Nominal center frequency (fo)	10.695 MHz
Pass bandwidth	±7.5 kHz or more at 3 dB
Attenuation bandwidth	±25 kHz or less at 40 dB ±45 kHz or less at 60 dB
Guaranteed attenuation	70 dB or more within ±1 MHz Spurious level = 40 dB or more at fo ~ fo +500 kHz Spurious level = 80 dB or more at fo − (910 kHz ±10 kHz)
Ripple Loss	1.0 dB or less 1.5 dB or less
Impedance	3 kΩ/0 pF

Table 2. MCF (L71-0216-05) (RX Unit: XF1)

Item	Rating						
Nominal center frequency	A: 10.7 MHz (RED) B: 10.67 MHz (BLUE) C: 10.73 MHz (ORANGE) D: 10.64 MHz (BLACK) E: 10.76 MHz (WHITE)						
3 dB bandwidth	280±50 kHz						
20 dB bandwidth	650 kHz or less						
Ripple	0.5 dB or less						
Loss	6 dB or less						
Spurious response	30 dB or more at 9 ~ 12 MHz						
Input and output impedance	3300						

Table 3 Ceramic filter (L72-0014-05) SFE10.7MA5 (RX unit: L7)

Item	Rating
Nominal center frequency	455 kHz±1 kHz
6 dB bandwidth	±6 kHz or more
50 dB bandwidth	±12.5 kHz or less
Ripple (within 455 ±4 kHz)	3 dB or less
Loss	6 dB or less
Guaranteed attenuation (within 455±100 kHz)	35 dB or more
Input and output impedance	2.0 kΩ

Table 4. Ceramic filter (L72-0315-05) CFW455F (RX Unit: L10)

TX Section (X55-1270-10, X45-1150-10)

The microphone and Touch Tone signals are amplified by Q29 and fed to the FM modulator vari-cap diode D20 through the MIC amplifier Q30 and splatter filter to produce an FM signal. The 10.695 MHz signal from the oscillator circuit Q31 is applied to the transmit balanced mixer (Q33. Q34) via buffer amplifier Q32. The 144 MHz signal obtained from the balanced mixer is fed through the 4-stage BPF (with voltage variable tuning) to eliminate unwanted spurious components.

This signal is then amplified by Q35 and 36 to drive the final unit. Both Q36 and the Final unit are powered by the DB Line, which also functions at low power and during protection. The DB circuit is a 12.4V AVR (Automatic Voltage Regulator) circuit using Q2-5 and D5.

The signal to the Final unit is power amplified by the power hybrid Q6. It passes through the transmit/receive antenna switch diodes D1, D2, harmonics are eliminated by LPF (Low Pass Filter), and the signal is then applied to the ANT terminal.

The protection circuit is an automatic reset VSWR detector. DB voltage is dropped by driving Q1 with the reflected output component. Low power control is effected by RL1, which switches the power hybrid FB terminal over to the DB line. Power is reduced to 5W by controlling the DB line with VR4.

Item	Symbol	Tc (°C)	Rating		
Operating voltage	Vcc	25	17V		
DC current	icc	25	6A		
Operating case temperature	Tc (op)	-	-30~+110°C		
Storage temperature	Tstg	-	-40 ~ + 110°C		
Base bias voltage	VBB	25	10V		

Table 5. Power module (V30-1171-60) M57733 MAX Rating (Final Unit: Q6)

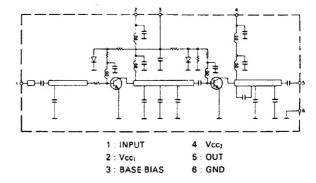


Fig. 1 Power module (V30-1171-60) Equivalent Circuit

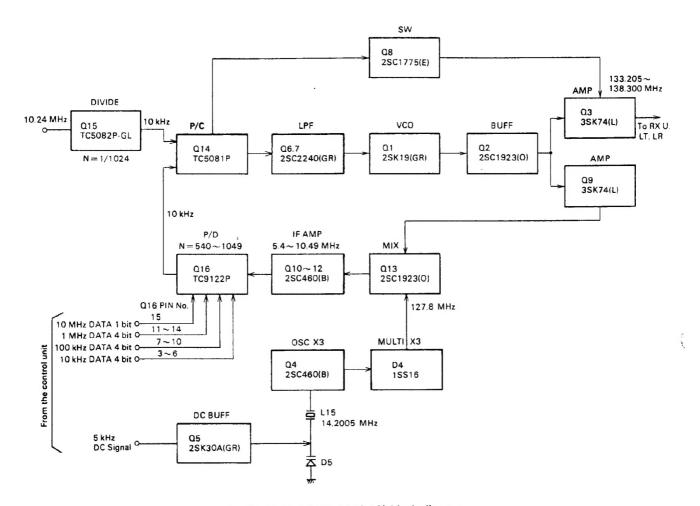


Fig. 2 PLL Unit (X50-1650-10) block diagram

S Meter Circuit (X54-1510-10)

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The digital S meter circuit uses ICs and LEDs to indicate input signal strength.

When the receive signal is about 0 dB μ , the first LED will light. Refer to S meter sensitivity on page 33 for the signal level at which each LED lights. When the signal level is about 20-30 dB, all LEDs will light. In the transmit mode, 5 LEDs will light at "Hi" power, and 3 LEDs at "Low" power.

Backup Circuit (X55-1270-10)

- 1. Backup, power cord connected.
 - When the power cable is connected to the vehicles battery. 13.8V is available at the BB terminal even at Power switch OFF; this AVR circuit (Q26, D16 and D17) supplies 5.2V to the MB terminal.
 - When the Power switch is ON, Q26 is turned OFF by Q25 and memory power is available directly from the control unit.
- 2. Backup, power cable disconnected.
 - With Ni-Cd cells installed in the battery case. Q28 is turned ON, and 5.2V is fed from the BT line through Q28 to the MB line. When the Power switch is ON, the 8V AVR circuit is activated by Q27 and the Ni-Cd's are charged through R94 and D19.
- 3. Backup Hold Time.
 - During engine start-up, voltage at the battery terminal drops. C6 and C7 in the control unit afford about 1.5 sec of backup time

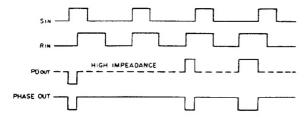


Fig. 3 TC5081P (PLL Unit : Q14)

Phase comparator timing chart

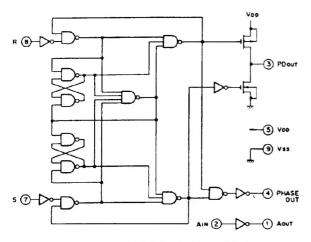


Fig. 4 TC5081P (PLL Unit: Q14)

- When the Ni-Cd batterie's are fully charged, the backup hold time is about 1 week max. And normally about 5 days.
- If backup greater than 1 week is required, 13.8V DC ±20% should be applied through the Ext. Backup terminal.

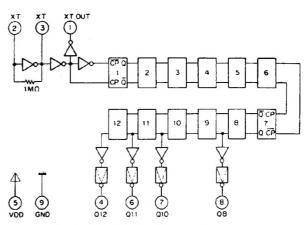


Fig. 5 TC5082P-GL (PLL UNIT: Q15)

PIN NO	8	7	6	4	1
PIN NAME	Q ₈	Q ₁₀	Q ₁₁	Q ₁₂	XTout
Dividing ratio	1/256	1/1024	1/2048	1/4096	1/1
Output frequency X-tal 10.24 MHz	40 kHz	10 kHz	5 kHz	2.5 kHz	10.24 MHz

Table 6.

TC5082P-GL (PLL Unit: Q15)

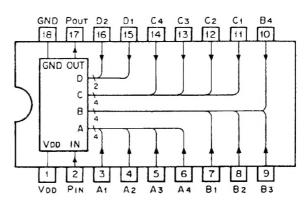


Fig. 6 TC9122P (PLL Unit: Q16)

Sympol		Name		Content and operation								Remarks					
Pin	Programm	nable counter minal	Programmable counter input terminal to which the signal to be divided is input										be	Build-in bias circuit			
Pout	Programm output re	nable counter izminal	ino	Programmable counter output terminal. Output is 1/N of the nout frequency. The output@ulse width equals 5 bit of the input.									,				
A, ~ A. B. ~ B.	> 1 > 10 Program input						e div		ratio	Th	e foli	QW IO	g inp	ut			Built-in pull-down
C C.	, 100	rerminals	Α,	A,			в,		Ðι	8.	c,	C,	C,	C.	D,	D:	resistor
D, ~ D.	1000		1.1	0	٥	0	0	0	0	0	0	0	0	0	0	0	
	i		: 0	1	0	0	0	0	0	0	0	0	٥	Q	0	0	
	!		1	1	0	0	0	0	0	0	0	0	0	Q	0	0	1
1	1		0	0	1	0	0	0	0	0	0	0	0	0	0	0	1
			1	0	1	0	0	D	0	0	0	0	0	O	0	0	1
	1		0	1	1	0	0	0	0	0	0	0	0	O	0	0	l
			1 1	1	,	0	0	0	٥	0	0	0	0	0	n	0	I

Table 7. Functions of TC 9122P (PLL Unit: Q16)

Table. 8 Micro-Processor Functions (μPD650C-037 Control Unit, Q18)

Terminal No.	Name of terminal	Input signal	Output signal	Description	Pulse
1	CL1			Clock frequency: 346 kHz	
2	PCO	0		Normal: L Transmit: H	
3	PC1	0		Squelch open: H Squelch OFF: L	
4	PC2		0	PO, PA, MR, ST common output CH display: 10-digit signal	0
5	РС3		0	Rev., TX OFFSET, 600/700 common output CH display: 1-digit signal	
6	INT	0		Normal: H	
7	RES	0		Normal: L	
8	PDO		0	Display BCD output A: Latch address output A0	0
9	PD1		0	Display BCD output B: Latch address output A1	c
10	PD2		0	Display BCD output C: Latch address output A2	0
11	PD3		0	Display BCD output D: Latch data output D	0
12	PEO		0	Frequency display, 1 kHz digit: CL, 0, MW touch tone R4	0
13	PE1		0	Frequency display, 10 kHz digit: 7, 8, 9 touch tone R3	0
14	PE2		0	Frequency display, 100 kHz digit: 4, 5, 6 touch tone R2	0
15	PE3		0	Frequency display, 1 MHz digit: 1, 2, 3 scan touch tone R2	0
16	PFO		0	PLL data output, 10 kHz digit: Lat 146,000	
17	PF1		0	PLL data output, 10 kHz digit: Lat 146.000	
18	PF2		0	PLL data output, 10 kHz digit: Lat 146.000	
19	PF3		0	PLL data output, 10 kHz digit: Lat 146.000	
20	TEST			Power supply, 5V	
21	vcc			Power supply, 5V	_
22	PGO		0	PLL data output, 100 kHz digit: H at 145.000	

Terminal No.	Name of terminal	Input signal	Output signal	Description	Pulse
23	PG1		0	PLL data output, 100 kHz digit: Lat 146.000	
24	PG2		0	PLL data output, 100 kHz digit: H at 146,000	
25	PG3		0	PLL data output, 100 kHz digit: Lat 146.000	
26	РНО		0	PLL data output, 1 MHz digit: H at 146.000	
27	PH1		0	PLL data output, 1MHz digit: H at 146.000	
28	PH2		0	PLL data output, 1 MHz digit: H at 146.000	
29	PH3		0	PLL data output, 1 MHz digit: Lat 146.000	
30	PIO		0	PLL data output, 5 kHz	
31	PII		0	PLL data output, 10 MHz	
32	PI2		0	Latch timing pulse output	0
33	PAO	0		Rotary encoder UP input	0
34	PA1	0	<u> </u>	Rotary encoder DOWN input	0
35	PA2	0		MIC UP input; UP at L, Stops when both are L	
36	PA3	0		MIC DOWN input: DOWN at L. Stops when both are L.	
37	РВО	0		700 at H of 600/700 selector, C3 5 kHz at H of step selector, C2 Scan input E3 Destination E0 1. 0 1.0 E1 1 0 0.0 K X W	
38	PB1	0		Reverse input C3, MW input E0: MR input C2 7E1, 4E2, 1E3, touch tone B1	
39	P82	0		⊝ shift input C3: P.O input, C2 OEO, 8E1, 5E2, 2E3: Touch tone B2	
40	РВЗ	0		⊕ shift input C3, touch tone B3: P,A input C2 CL, E0, 9E1, 6E2, 3E3: Simplex input C3 (common to B2)	
41	vss			Earth (Ground)	
42	CL			Clock frequency: 346 kHz	

PLL Unit (X50-1650-10)

Fig. 2 shows a basic block diagram of the PLL circuit. The VCO signal from Q1 is buffered by Q2 and amplified by Q9. It is then mixed with the heterodyne signal by Q13 to produce a 5.4-10.49 MHz signal.

This signal is filtered and then amplified by Q12-10, and then frequency divided by Q16 according to the binary data (10 MHz, 1 MHz, 100 kHz and 10 kHz order) from the control unit to obtain a 10 kHz step signal.

The 10.24 MHz signal from the RX unit is frequency divided

1/1024 by Q15 to a 10 kHz reference signal is then phase detected by Q14. This signal, through low pass filters Q6 and Q7, is applied via the CV line to the vari-cap diodes D21-24 in the RX unit as a control voltage. In the VCO HET circuit, a 14.2 MHz crystal controlled signal is generated by OSC Q4, and is multiplied 9X by D4 to obtain 127.8 MHz signal, which is applied to the mixer Q13.

Vari-cap D5 in the crystal oscillator circuit shifts the oscillator frequency +5 kHz through the Q5 source voltage variation, derived from the control unit 5 kHz DC signal.

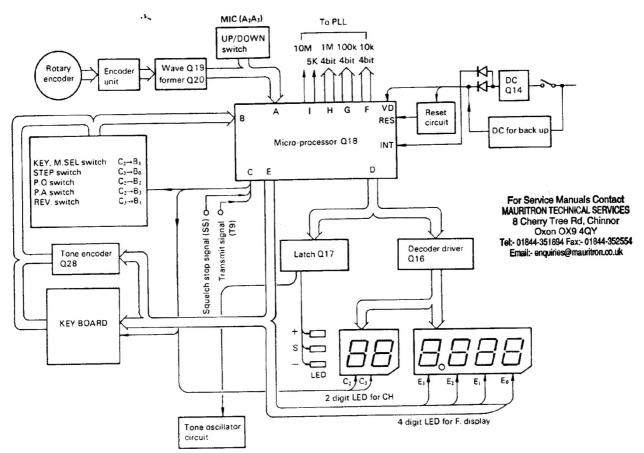


Fig. 7 Control Unit block diagram

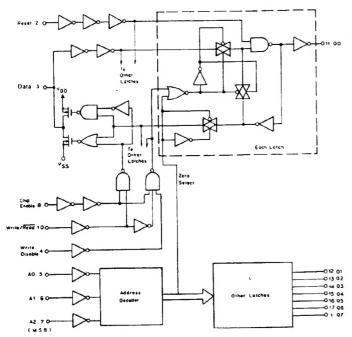


Fig. 8 Function diagram of MC14599B (Control Unit: Q17)

TI	RUTH TA	BLE				
Chip Enable	Write/ Read	Write Disable	Reset	Addressed Latch	Other Latches	Data Pin
0	×	×	0			Z
1	1	0	0	Data	•	Input
1	1	1	0			Z
1	0	×	0		•	Qn
×	×	×	1	0	0	Z/0

× = Don't care.

No change in state of latch.

Z = High impedance.

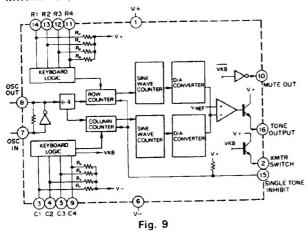
On = State of addressed latch.

Table 9. Truth table (Control Unit: Q17)

Table 10. Control Unit Q16 (SN74LS247N) function

DECIMAL		1	NPI	JTS						O U	TPU	TS		\Box	
OR FUNCTION	l.T	RBI	D	С	В	A	BI/RBO	a	t	С	d	e	ſ	R	
0	н	Н	L	i.	1.	I.	н	ON	ON	ON	ON	ON	ON	OFF	
Ÿ	н	x	ĩ	ï	i.	Н	н	OFF	ON	ON	OFF	OFF	OFF	OFF	
,	н	Î x	ĭ	ī.	Н	i.	н	ON	ON	OFF	ON	ON	OFF	ON	
1	н	×	ũ	I.	н	H	н	ON	0.5	ON	ON	OFF	OFF	ON	
	н	x	L.	H	1.	L	н	OFE	0.5	ON		OFF		ON	
5	11	x	ï.	н	L	H	H	ON	OFF	ON	ON	OFF	ON	ON	
6	н	x	i.	н	Н	L	н	ON	OFF	ON	ON	ON	ON	ON	
7	H	l x	ì.	H	Н	H	н	ON	0.5	ON	OFF	OFF	OFF	OFF	
8	H	X	н	L	L	-L	Н	ON	OV.	ON	ON	ON	ON	ON	
9	н	X	н	L	L	H	н	ON	ON	ON	ON	OFF	ON	ON	
10	lн	x	Н	L	н	L	н	OFF	DFF	OFF	ON	ON	OFF	ON	ł
11	н	X	н	L	Н	н	H	OFF	OFF				OFF	ON	1
12	H	X	н	н	l.	L	H	OFF	ON	OFF	OFF		ON	ON	1
13	н	X	н	н	L'	н	H	ON	055	OFF	ON	OFF	ON	ON	}
14	н	X	н	н	Н	L	н			OFF		ON	ON	ON	1
15	H	1 x	н	H	Н	Н	н						OFF		<u> </u>
81	X	X	X	X	X	X	L						OFF		l
RB!	н	L	L	L	L	L	L	OFF	OFF					OFF	
LT	1 1	X	x	X	X	X	н	ON							

MK5087 (N) (Control Unit Q28)



Control Unit (X53-1180-10)

The Control unit has an LED dynamic display to indicate frequency in 4 digits and storage channels in 2 digits. The BCD (Binary Coded Decimal) data in the micro-computer D port (pins 8-11) are converted into 7-segment data by the decoder driver Q16. Frequencies are displayed by the E port (pins 12-15), and channels by the C2 and C3 ports (Pins 4, 5), switching Q10-Q13 and Q5-Q6. TX OFFSET is displayed when the dynamic data from the D port is latched by Q17. The display lights in static mode through Q7-Q9.

PLL Data Output

The BCD codes for 10k, 100k and MHz are output from the F. G. and H ports (pins 16-19, 22-29) as PLL data output. The lo port is 5k/bit and the I1 port is 10M/bit. The data in the I2-F0 are 0550 for 4000, 0551 for 4005, 0650 for 5000, and 3495 for 8795.

Reset Circuit

The reset circuit is a voltage detector. When the voltage exceeds about 3.5V, Q1 is ON and Q2 is OFF, thereby applying pulses to Q18 pin 7 through the differentiation circuit C10 and R5 to reset the circuit.

Tone Oscillator Circuit When the latch Q17 pin 17 goes H, Q4 turns ON to activate the tone generator.

• Switch Circuits

Each switch functions when dynamic pulses from the micro-computer are input. Diodes are used to prevent reverse current flow.

Power Supply Circuits

The micro-computer power supply is Q14, a 6V AVR. Diode D3 provides reverse flow protection. Display power is Q15, a 5V AVR.

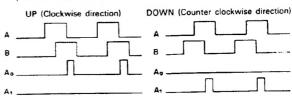


Fig. 10 Encoder input timing chart

Encoder Input

The encoder (25 clicks/turn) is a mechanical ON/OFF switch having a phase difference. The encoder circuit. Q19 and Q20 are used to prevent chatter and to shape waveform. A right turn inputs pulses to the Ao port (33), and a left turn to the A1 port (pin 34).

UP/DOWN

The micro-computer UP/DOWN inputs A2 (pin 35) and A3 (pin 36) are connected to the microphone switches and are normally H. The UP/DOWN function is effected at L.

Table 11.

	697 Hz	770 Hz	852 Hz
1209 Hz	1	2	3
1336 Hz	4	5	6
1477 Hz	7	8	9
1633 Hz	м .	0	C #

• Tone Encoder Circuit

In transmit mode, Q28 MK5078N is operated by the 8T (power) line. Q24-Q27 are OFF so the pulse signal from the micro-computer Q18 is cut off. By pressing buttons 1-9, O, C and M on the key board, the logical level is inverted: Q28 3-5 becomes L and 11-14 becomes H to produce 2-tone output at pin 16. Tone output deviation is adjustable by VR1. Table 11 shows the frequencies of the two signals.

Backup Circuit

When the power cable is connected to the power supply or batteries are installed, the CB line is at OV and the MB line is 5V at the power switch OFF position. Pins 6 and 35 of micro-processor Q18 (μ PD650C-037) are switched from H to L, thereby operating the backup circuit. At this time, all terminals of Q18 are set to L except for pins 1, 20, 21, 42. The backup function is reset when pin 35 becomes H.

Encoder Unit (X54-1500-10)

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The memory channel selector (25 clicks/turn) is a mechanical ON/OFF switch which phase inverts according to the direction of rotation. It is a Schmidt circuit using Q3 (6 inverter gates) to waveform shape the pulses at terminals EA and ED.

By using Q2 (4 NAND gates) and Q1 (4 NOR gates), the

rising and falling portions of the pulse are detected and fed to the terminals A, B, C and D. The signal is applied to Q19 of the control unit to separate the pulse by the rotational direction. The separated pulse width is set to about 3m sec by the one shot circuit Q20 to input the signal to the micro-processor Q18.

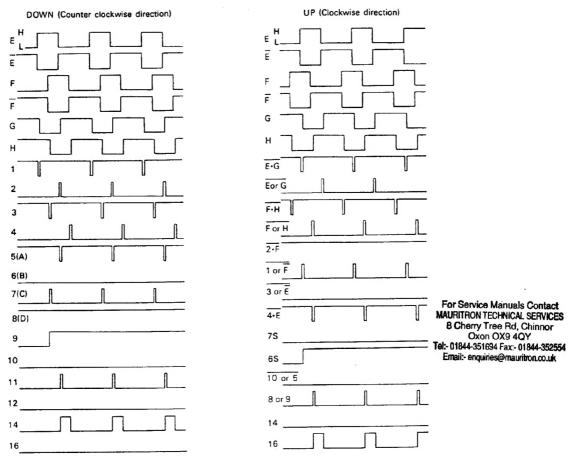


Fig. 11 Encoder Unit timing chart

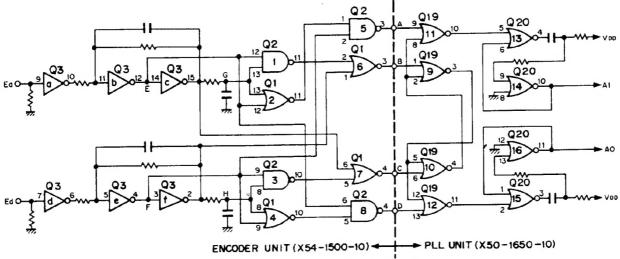
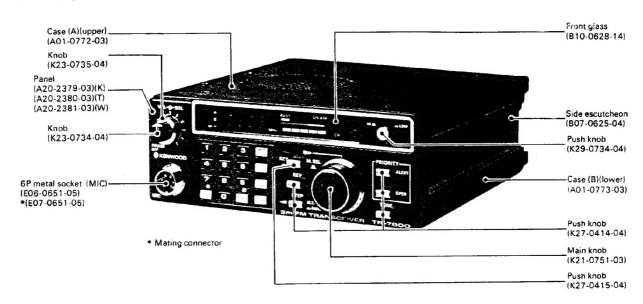


Fig. 12 Encoder, PLL Unit circuit diagram

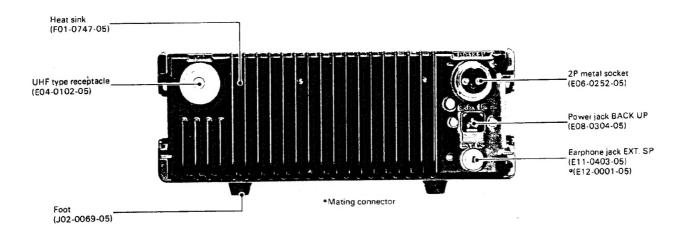
TR-7800

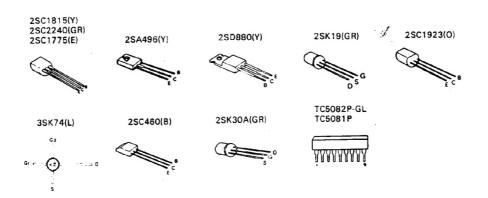
OUTSIDE VIEWS

<FRONT PANEL>



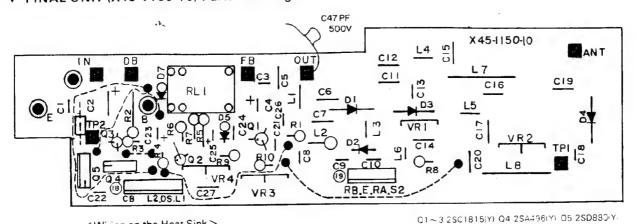
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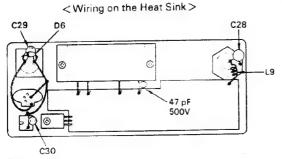




PC BOARD VIEWS

▼ FINAL UNIT (X45-1150-10) Parts list: Page 16





Note: 1 Solder the leads of the power module without applying stress

Install C28 and L9 as short as possible.

[Transistor Terminal Indication]

component side.

NOTES:

Q6 M57733 D1:MI402 D2 MI301 D3.4:IN60 D5 XZ 064 D6 U15B D7 1S1555

в

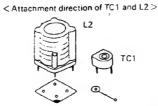
All printed circuit views are

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8 Cherry Tree Rd, Chinnor
Oxon OX9 4QY

Tel:- 01844-351694 Fax:- 01844-352554 Email:- enquiries@mauritron.co.uk

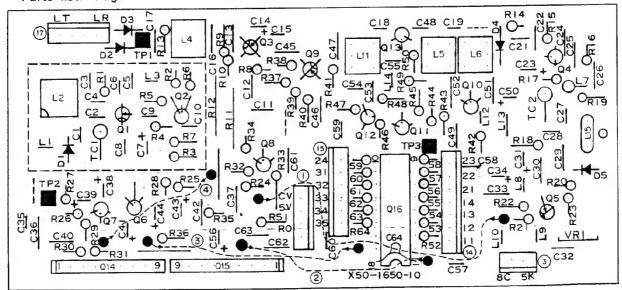
Soldered L15

< Attachment method of L15>



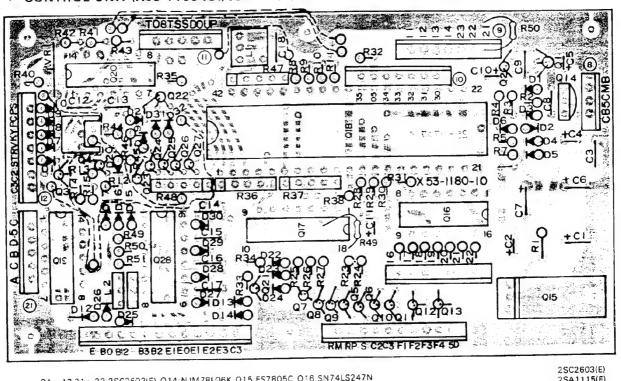
▼ PLL UNIT (X50-1650-10)
Parts list: Page 17

O1 2SK19(GR) TRIO-5 Q2.13:2SC1923(O) Q3.9:3SK74(L) Q4.10 ~ 12:2SC460(B Q5 2SK30A(GR) Q6.7 2SC2240(GR) Q8 2SC1775(E) Q14:TC5081P Q15 TC5082P-G1 Q16 TC9122P D1 1SV50S D2.3:1S2588 D4:1SS16 D5:1S2208



PC BOARD VIEWS

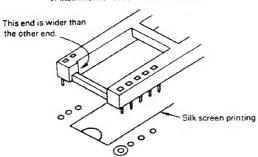
▼ CONTROL UNIT (X53-1180-XX) XX: 10(K), 61(W)(T) Parts list: Page 17



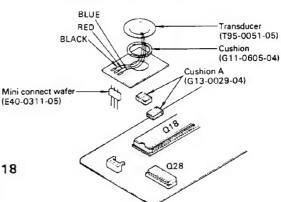
Q1 ~ 13.21 ~ 23.2SC2603(E) Q14·NJM78L06K Q15.FS7805C Q16 SN74LS247N Q17:MC14599B Q18 μ^2 D650C-037 Q19.20·TC4001BP Q24 ~ 27.2SA1115(E) (K) Q28·MK5087N (K) D1 X2-060 D2 ~ 11.13 ~ 17.19 ~ 24 1S1555 D12.25.26:1N60 D27 ~ 32 1S1555 (K) D33 ~ 36:1S1555 (W)



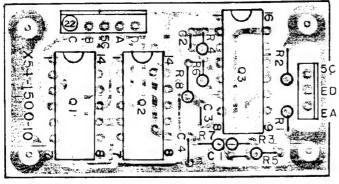
< Attachment direction of the IC socket >



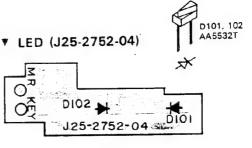
< Attachement method of the transducer >



▼ ENCODER UNIT (X54-1500-10) Parts list: Page 18



Q1 TC4001BP Q2:TC4011BP Q3:TC4049BP



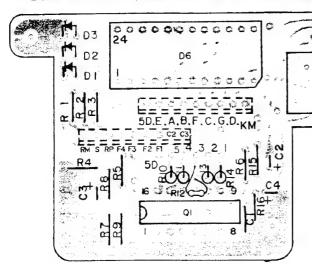
D101,102: AA5532T

PC BOARD VIEW/IC.LED DATA

D8

D8:TLM8051

▶ DISPLAY UNIT (X54-1510-10) Parts list: Page 18



For Service Manuals Contact
MAURITRON TECHNICAL SERVICES
8 Cherry Tree Rd, Chinnor
Oxon OX9 4QY Tel:- 01844-351694 Fax:- 01844-352554

		Email:	enquines	@mauritron.co.uk	
Pin No.	Connection	TLR4135	Pin No.	Connection	TLR4135
1	PM	Cathode	13	Dot 1	Cathode
2	Dot 3	Cathode	14	Dot 1	Anode
3	Upper Colon	Cathode	15	Dot 2	Anode
4	Lower Colon	Cathode	16	Unit M Common	Anode
5	Ε	Cathode*	17	10's M Common	Anode
6	А	Cathode*	18	Upper Colon	Anode
7	В	Cathode	19	Unit H Common	Anode
8	۴	Cathode*	20	10's H Common	Anode
9	С	Cathode	21	Lower Colon	Anode
10	G	Cathode*	22	Dot 3	Anode
11	D	Cathode*	23	AM & PM Common	Anode
12	Dot 2	Cathode	24	AM	Cathode

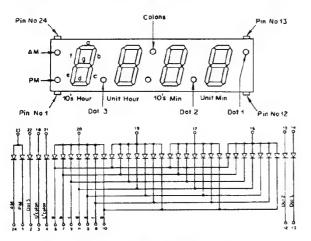
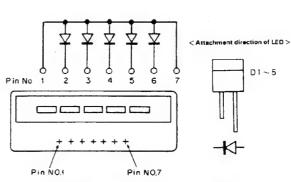


Fig. 13 TLR4135 (Display Unit D6)



Q1:LB1409 D1,3.5.PR5532K D2,4:PY5532K D6:TLR4135 D7:TLR323

00000

01-01

2

Fig. 14 TLM8051 (Display Unit D8)

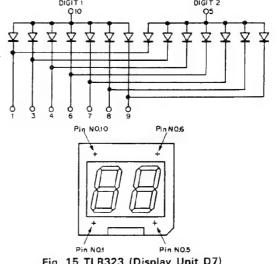


Fig. 15 TLR323 (Display Unit D7)

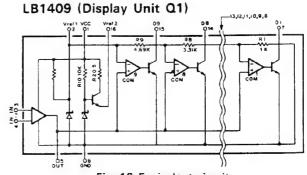
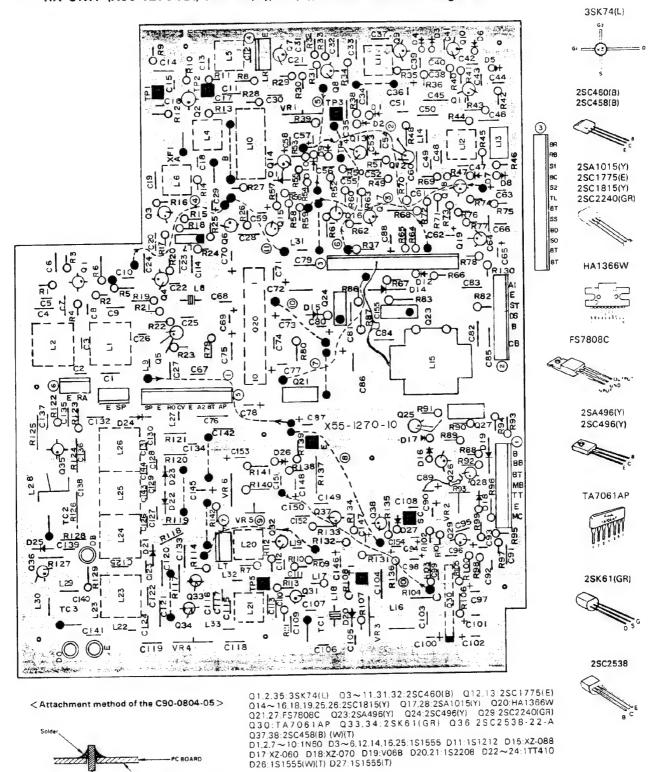


Fig. 16 Equivalent circuit

PC BOARD VIEW

▼ RX UNIT (X55-1270-XX) XX: 10(K), 51(T), 61(W) Parts list: Page 18



0 001 µF (C90-0804-05)

Note 1: T: Britain W. Europe X: Australia K USA

Only special type of resistors (example: cement, metal film, etc.) and capacitors (example: electrolytic, tantalum, mylar, temp, coeff, capacitors) are detailed in the PARTS LIST. For the value of all common type components, refer to the schematic diagram of the P.C. board illustration. Resistors not otherwise detailed are carbon type (1/4W or 1/8W) Order carbon resistors and capacitors according to the following example

A carbon resistor's part number is RD14BY 2E222J

A ceramic capacitor's number is CK45F1H103Z, CC45TH1H220J

RESISTOR

1. Type of the carbon resistor



RD148Y RD 1488 (small size)



2. Wattage

$$1W \rightarrow 3A$$
 $3W \rightarrow 3F$ $5W \rightarrow 3H$ $2W \rightarrow 3D$ $4W \rightarrow 3G$

3' = CC45 0 0 ...

Ceramic capacitor (type I) temperature coeff capacitor 1' 3'

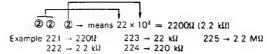
1st word	C	L	P	R	S	T	U
(Color)	(Black)	(Red)	(Orange)	(Yellow)	(Green)	(Blue)	(Violet)
ppm/ C	0	-80	- 150	-220	- 330	-470	

3 = CK45 O

Ceramic capacitor (type II) 3

Cord	В	D	Ε	F
Operating temperature	-30	- 30	-30	- 10
C	+85	+ 85	+85	+ 70

3. Resistance value



4. Tolerance

$$J = \pm 5\% \text{ (Gold)} \qquad K = \pm 10\% \text{ (Silver)}$$

CAPACITORS

Type	1	Туре II									
CC	45	TH	1H	220	J	CK	45	F	1H	103	Z
1'	2	3.	4	5	6	1	2	3	4	5	6
1 =	Type	Çĕ	ramic	elect	rolytic.	etc	4 =	Voltag	ge rati	ng	
2 =	Shape	:	ound.	square	e. etc		5 =	Value			
3 =	Temp	range	€				6 =	Tolera	ance		
3' =	Temp	coei	cent								

Ex. CC45TH = $-470 \pm 60 \text{ ppm/°C}$

ſ	2nd Word	G	Н	J	К	L
ľ	ppm/ C	: 30	±60	±120	±250	±500

5 = Capacitor value

Example 010 → 1 pF 100 → 10 pF 101 → 100 pF $102 \rightarrow 1000 \, pF = 0.001 \mu F$ 103 → 001 µF

6 = Tolerance

1	Cord	С	D	G	J	K	М	Х	Z	Р	No cord
	(%)	±0.25	±0.5	±2	±5	±10	±20	+ 40 20	+ 80 - 20		More than $10 \mu\text{F} - 10 \sim +50$ Less than $4.7 \mu\text{F} + 10 \sim +75$

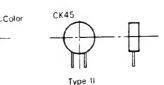
Less than 10 pF

Cord	В	С	D	F	G
(pF)	±0.1	±0.25	±0.5	±1	±2

Abbreviation		Abbreviation	
Сар.	Capacitor	ML	Mylar
С	Ceramic	S	Styren
ε	Electrolytic	T	Tantalum
MC	Mica		

CC45

Type !



GENERAL

☆: New Parts

Ref. No.	Parts No.	Description	Re- marks
_	A01-0772-03	Case (A) Upper	4
-	A01-0773-03	Case (B) Lower	<u></u>
_	A13-0612-02	Angle ass'y (right)	
-	A13-0613-02	Angle ass'y (left)	
_	A13-0614-04	Angle (top)	
-	A20-2379-03	Panel (K)	TÎ.
_	A20-2380-03	Panel (T)	☆
_	A20-2381-03	Panel (W)	☆
-	803-0516-04	Switch mask × 6	益
	B05-0701-04	Speaker grill cloth	
-	805-0713-04	Grill cloth (Tone oscillator)	
-	B07-0625-04	Side escutcheon × 2	☆

Ref. No.	Parts No.	Description	Re- marks
_	807-0626-03	Front escutcheon	π̈́
_	B10-0628-14	Front glass	☆
-	842-1685-04	Switch plate (H/L)	*
_	B46-0058-00	Warranty card (K)	
	B50-2727-00	Operating manual (K)	*
_	B50-2728-00	Operating manual (T)	*
	B50-2729-00	Operating manual (W)	*
-	E06-0651-05	6P Metal socket (MIC)	
_	E07-0252-05	2P Metal Socket (DC cord ass'y)	
_	£12-0001-05	Earphone plug	
_	E29-0412-05	1P Connector (male)	
	E29-0413-05	1P Connector (female)	
-	E30-1674-05	DC cord ass'y	

Ref. No.	Parts No.	Description	Re- marks
_	E31-0456-05	Plug with lead (SP)	
_	F05-8021-05	Fuse (8A)	
_	G02-0505-05	Knob spring AF	
-	G09-0411-05	Knob spring SQL	ú
-	G13-0628-04	Cushion (battery)	☆
-	G53-0511-04	Packing × 8 (case)	☆
-	H01-2683-03	Carton case (inside) (K) (W)	☆
_	H01-2684-03 H10-2501-03	Carton case (inside) (T)	☆
_	H10-2534-02	Styrene foam cushion (upper) Styrene foam cushion (lower)	쇼
_	H25-0049-03	Accessories bag	-
-	H25-0079-04	Protective bag (MIC)	1
-	H25-0103-04	Protective bag (cord)	
-	H25-0106-04	Protective bag	
-	J02-0069-05	Foot × 2 (small, Rear)	
-	J02-0070-05	Foot × 2 (large, Front)	
-	J19-1334-05	Battery case	☆
_	J21-0392-04	Lead holder	
_	J21-2504-04 J31-0514-04	Speaker mounting plate Spacer collar H/L	
_	J32-0745-04	Round boss × 5	☆
_	J32-0746-04	Hex, boss	☆
-	J42-0409-04	Knob bush H/L	
-	J61-0019-05	Viny letie × 2	
-	K21-0751-03	Main knob	☆
-	K23-0734-04	Knob (AF)	拉
-	K23-0735-04 K27-0414-04	Knob (SQL) Push knob × 5	쇼
_	K27-0415-04	Push knob (KEY, M. SEL)	\ \\ \.
-	K29-0734-04	Push knob HI/LOW	₩
-	N09-0008-04	Screw × 4 (angle)	
-	NO9-0256-05	Ground screw	1
-	N09-0619-05	Plastic screw × 2 (battery)	₩ .
-	N14-0508-04	Spanner nut	
_	N14-0510-04 N14-0516-05	Flange nut × 4 (angle)	
_	N15-1040-46	Speed nut × 2 Flat washer × 4 (angle)	
_	N15-1060-41	Flat washer × 4 (angle)	
_	N16-0060-41	Spring washer × 4 (angle)	
_	N30-3006-46	Screw × 2	
-	N30-3008-11	Screw × 2	
-	N33-3006-45	Round flat screw (case, etc.)	
-	N99-0304-04	Allen head bolt × 4 (angle)	
-	R19-9404-05	Pot.50kΩ (B), 10kΩ (K)	Δ
	\$40.2402.05	Bush switch 11/1	
_	\$40-2403-05 \$40-2415-05	Push switch H/L Push switch (K, T) × 5, (W) × 4	4
_	\$40-2416-05	Push switch (K, T) × 1, (W) × 2	*
-	\$59-0406-05	Key board ass'y	*
-	T03-0027-15	Speaker	
-	T91-0311-05	Microphone (TRIO) (T)	
	T91-0313-05	Microphone (KENWOOD) (K) (W)	i 1

Ref. No.	Parts No.	Description	Re- marks
D101,102	V30-1170-06	LED AA5532T	垃
_	W01-0401-04	Allen kay	
-	W02-0315-05	Rotary encoder	耸
-	X45-1150-10	Final unit	☆
-	X50-1650-10	PLL unit	☆
-	X53-1180-10	Control unit (K)	
-	X53-1180-61	Control unit (W) (T)	☆
-	X54-1500-10	Encoder unit	☆
-	X54-1510-10	Display unit	蛇
-	X55-1270-10	RX unit (K)	☆ :
-	X55-1270-51	PX unit (T)	並
-	X55-1270-61	RX unit (W)	±

FINAL UNIT (X45-1150-10)

Ref. No.	Parts No.		Descrip	Description		
C2	CE04W1C221Q	E	220µF	16V		
C4	CE04W1C101Q	Ε	100μF	16V		
C5	CC45SL2H070D	С	7pF	±0.5pF		
C6	CC45SL2H080D	C	8pF	±0.5pF	1	
C7	CC45SL2H101J	С	100pF	±5%	1	
C10	CC45CH1H330J	C	33pF	±5%		
C11	CC45SL2H101J	C	100pF	±5%		
C12	CC45SL2H330J	C	33pF	±5%		
C13	CC45CH1H0R5C	c	0.5pF	±0.25pF		
C15	CC45SL2H390J	C	39pF	±5%		
C16	CC45SL2H100D	С	10pF	±0.5pF	ĺ	
C17	CC45SL2H02OC	С	2pF	±0.25pF		
C19	CC45SL2H22OJ	c	22pF	±5%	-	
C23	CS15E1VR47M	T	0.47µF	35V		
C25	CS15E1C4R7M	• T	4.7µF	16V		
C28	CC45SL2H120J	C	12pF	±5%		
	504.0400.05					
_	E04-0102-05		receptacle			
_	E06-0252-05	2P Metal			1	
- - -	E08-0304-05	-	k (BACK UI	P)	1	
_	E11-0403-05	Earphone	-			
_	E23-0046-04	Square te				
-	E23-0401-05	Round ter		_	1	
-	E40-0473-05	1	ect wafer 4		ĺ	
_	E40-0573-05	Mini conn	ect wafer 5	Р		
_	F01-0747-05	Heat sink			₩	
_	F20-0078-05	MICA inst	lator (Q5)			
-	F29-0014-05	Shoulder	washer (Q5)		
.1	L34-0823-05	VHF coil		3T		
-2	L34-0438-05	Coil	0.9	ЭμН		
.3	L34-0692-05	VHF coil	5ϕ	4T		
.4	L34-0817-05	VHF coil	5φ	3T		
L5	L34-0823-05	VHF coil	5ϕ	3T		
L6	L40-1511-03	Ferri-induc	tor 15	ЮμΗ		
-7.8	L33-0025-05	Choke coil	1μ	Н		
.9	L34-0887-05	VHF coil	5φ	3T		
/R1	R12-5024-05	Trim. pot	10	OkΩ (2 potes)		

Ref. No.	Parts No.		scription	Re- marks
VR2	R12-0048-05	Trim. pot	100Ω	
VR3	R12-4016-05	Trim. pot	50kΩ	
VR4	R12-0042-05	Trim. pot	500Ω	
-	R92-0150-05	Short jumper × 2	2	
RL1	S51-1404-05	Relay		
01~3	V03-1815-06	TR	2SC1815 (Y)	
Q 4	V01-0113-05	TR	2SA496 (Y)	
Q.5	V04-0880-16	! TR	2SD880 (Y)	
Q6	V30-1171-60	Power module	M57733	Ė
D1	V11-5260-16	Diode	M1402	
D2	V11-0255-05	Diode	MI301	!
D3,4	V11-0051-05	Diode	1N60	!
D5	V11-4104-20	Zener diode	XZ-064	-
D6	V11-6460-26	Diode	U15B	1 4
D7	V11-0076-05	Diode	181555	

PLL UNIT (X50-1650-10)

	Ref. No.	Parts No.		Descripti	on	Re
	C1	CC45PG1H080D	С	8pF	±0.5pF	
	C2	CC45CH1H060D	C	6pF	±0.5pF	
	C3	CC45CH1H0R5C	, C	0.5pF	±0.25pF	
	C4	CC45CH1H060D	: C	6pF	±0.5pF	
	C5	CC45CH1H150J	C	15pF	±5%	
	C6	CC45CH1H030C	С	3pF	±0.25pF	l
	C7	CE04W1A101Q	ε	100µF	10V	
	C9	CC45CH1H040C	С	4pF	±0.25pF	
	C11	CC45CH1H020C	C	2pF	±0.25pF	
	C12	CC45CH1H22QJ	: C	22pF	±5%	
	C15	CE04W1C100Q	E	10µF	16V	1
	C16	C91-0457-05	: C	0.022µF	±10%	
	C18	CC45CH1H030C	C	3pF	±0.25p₽	
	C19	CC45CH1H0R5C	C	0.5pF	±0.25pF	
	C21	CC45CH1H220J	C	22pF	±5%	
	C23	CE04W1A470Q	ε	47µF	10V	
	C24,25	CC45CH1H101J	С	100pF	±5%	
	C27	CC45UJ1H180J	C	18pF	±5%	
	C28	CC45UJ1H100D	С	10pF	±0.5pF	
	C29	CC45UJ1H390J	С	39pF	±5%	ł
	C31	CS15E1VR47M	T	0.47µF	35V	
	C34	CE04W1A101Q	Ė	100μF	10V	
	C35	C91-0131-05	C	0.01µF	±10%	12
	C36	CQ92M1H473K	ML	0.047μF	±10%	
	C38	CS15E1C4R7M	İΤ	4.7μF	16V	İ
	C39	CS15E1C2R2M	T	2.2µF	16V	
	C40	CQ92M1H223K	ML	$0.022 \mu F$	±10%	
	C41	CE04W1E4R7Q	E	4.7 _{\psi} F	25V	ì
	C43	CE04W1H010Q	Ε	1µF	50V	
i	C44	CE04W1A101Q	Ε	100µF	10V	
ĺ	C48	CC45CH1H030C	С	3pF	±0.25pF	
	C49	CC45SL1H101J	С	100pF	±5%	
	C50	CE04W1A470Q	Ε	47µF	10V 5	
	C52	CQ92M1H223K	ML	0.022µF	±10%	
	C53	CC45SL1H101J	C	100pF	±5%	
	C54.55	CC45CH1H100D	С	10pF	±0.5pF	
	C56	CE04W1A101Q	E	100µF	10 V	

Ref. No.	Parts No.	Description	Re- marks
C63	C91-0457-05	C 0.022µF ±10%	
C65	CC45UJ1H070D	C 7pF ±0.5pF	
-55	0043031110705	C /pr ±0.5pr	
TC1	C05-0062-05	Ceramic timmer 6pF	
TC2	CO5-0031-15	Ceramic timmer 10pF	
-	E23-0046-04	Square terminal × 3	
-	E40-0273-05	Mini connect wafer 2P	
-	E40-0473-05	Mini connect wafer 4P	
-	E40-0673-05	Mini connect wafer 6P	
_	E40-0773-05	Mini connect wafer 7P	
1	,		
L1	L40-3391-03	Ferri-inductor 3.3µH	İ
L2	L32-0624-05	Oscillating coil VCO	
L3	L40-3391-03	Ferri-inductor 3.3µH	
L4	L34-0820-05	Tuning coil	
L5.6	L34-0901-05	Tuning coil	
L7	L33-0631-05	Choke coil 4.7μH ±5%	- 1
L8.9	L40-1021-03	Ferri-inductor 1mH	
L10	L40-4711-03	Ferri-inductor 470µH	l
L11	L34-0683-05	Tuning coil	- 1
L12,13	L40-1021-03 L40-1501-03	Ferri-inductor 1mH	
L15	L77-0855-05	Ferri-inductor 15 _µ H Crystal 14,2005 MHz	
L16	L40-4711-03	Crystal 14,2005 MHz Ferri-inductor 470µH	İ
	I THE WAY OF THE PARTY OF THE P		
·VR1	R12-4020-05	Trim. pot 50kΩ	
-	R92-015 0-05	Short jumper x 3	
Ω1	V09-1001-16	FET 2SK19 (GR) TR10-5	
02	V03-1001-16 V03-1923-06	FET 2SK19 (GR) TR10-5 TR 2SC1923 (0)	
03	V09-1002-56	FET 3SK74 (L)	ļ
Q4	V03-0079-05	TR 2SC460(B)	1
Q5	V09-0060-05	FET 2SK30A (GR)	
Q6,7	V03-2240-06	TR 2SC2240 (GR)	
Q8	V03-1775-06	TR 2SC1775 (E)	- 1
Q9	V09-1002-56	FET 3SK74(L)	
Q10~12	2 V03-0079-05	TR 2SC460 (B)	
Q13	V03-1923-06	TR 2SC1923 (O)	- 1
Q14	V30-1132-05	IC TC5081P	
015	V30-1133-J6	IC TC5082P-GL	
Q16	V30-1036-16	IC TC9122P	J
D1	V11-1260-36	Vari-cap diode 1SV50S	
D2.3	V11-0414-05	Diode 1S2588	-
D4	V11-0374-05	Diode 1SS16	
D5	V11-0317-05	Vari-cap diode 1S2208	

CONTROL UNIT (X53-1180-XX) XX: 10(K), 61(W)(T)

Ref. No.	Parts No.		Descripti	on	Re- marks
C1	CE04W1C331Q	E	330µF	16V	
C2	CE04W1A101Q	E	100µF	10V	
C4	CE04W1C470Q	E	47µF	16V	
C5	CE04W1A470Q	Ε	47µF	10V	
C6.7	CE04W1A471Q	E	470µF	10V	
C10	CE04W1H010Q	E	1μF	50V	
C11	CE04W1A101Q	Ε	100µF	10V	
C12.13	CQ92M1H393K	ML	0.039µF	±10%	
C18	CQ92M1H223K	ML	0.022µF	±10%	

For Service Manuals Contact
MAURITRON TECHNICAL SERVICES
8 Cherry Tree Rd, Chinnor
Oxon OX9 4QY
Tel:-01844-351694 Fax:-01844-352554
Email:-enquiries@mauritron.co.uk

Ref No.	Parts No.	Des	cription	Re- marks
	E02-0103-05	IC Socket	16P (K)	
_	E02-0106-05	IC Socket	42P	
_	E40-0311-05	Mini connect was	fer 3P	
_	E40-0373-05	Mini connect was	fer 3P	
_	E40-0573-05	Mini connect was	fer 5P	
_	E40-0773-05	Mini connect was	fer 7P	
_	E40-1073-05	Mini connect wa	fer 10P	
-	E40-1273-05	Mini connect wa	fer 12P	
		Cubica /Tanada	.narl	
-	G11-0605-04	Cushion (Transdi		
-	G13-0629-04	Cushion (A) (Trai	nsducer)	Ė
		$(K) \times 2(W) \times 1$		1 .
-	G13-0630-04	Cushion (B) (Trai	nsducer) (W)	菜
L1	L30-0503-05	IFT		
L2	L78-0003-05	Ceramic oscillato	or 3.58MHz (K)	
24	DC14AD2A2201	Metal film	33Ω±5%1W	
R1	RS14AB3A330J	Resistor block	27kΩ × 4	
R36	R90-0526-05	Resistor block	2.7kΩ × 4	1 2
R37	R90-0530-05	Resistor block	100kΩ × 4	1 %
R47	R90-0529-05	Resistor block	27kΩ × 4 (K)	"
R48	R90-0526-05	nesistor block	27811 ~ 4 1107	
VR1	R12-2015-05	Trim.pot	5kΩ (Κ)	
BZ1	T95-0051-05	Transducer		
01~13	V03-2603-06	TR	2SC2603 (E)	
Q14	V30-1067-06	IC	NJM78L06K	
015	V30-1165-06	IC	F\$7805C	12
Q16	V30-1030-56	IC	SN74LS247N	
Q17	V30-1166-06	IC	MC14599B	i
018	V30-1164-06	ic	μPD650C-037	
Q19.20	V30-1066-06	IC	TC4001BP	
Q21~23		TR	2SC2603 (E)	
024~27		TR	2SA1115 (E) (K)	
028	V30-1074-06	ic	MK5087N (K)	
		7 diada	V7 060	
D1	V11-4101-20	Zener diode	XZ-060 151555	
D2~11	V11-0076-05	Diode	1S1555 1N60	1
D12	V11-0051-05	Diode		
1	7 V11-0076-05	Diode	1\$1555	
D18		not used	10155	
1	4 V11-0076-05	Diode	181555	
D25.26	V11-0051-05	Diode	1N60	
	2 V11-0076-05	Diode	1S1555 (K)	
D33~3	6 V11-0076-05	Diode	1S1555 (W, T)	1

ENCODER	UNIT	(Y54-1	500-1	n)
FINCUDER	UNII	(人)サー	200-1	. ,

Ref. No.	Parts No.	Description	Re- marks
C1~4	CC45SL1H101J	C 100pF ±5%	
_	E40-0373-05 E40-0573-05	Mini connect wafer 3P Mini connect wafer 5P	

Ref. No.	Parts No.		Description	Re- marks
01	V30-1066-06	1C	TC4001BP	
02	V30-0301-70	IC	TC4011BP	
O3	V30-1009-26	IC	TC4049BP	

DISPLAY UNIT (X54-1510-10)

Ref. No.	Parts No.	Description			Re- marks
C2	CS15E1C010M	Т	1μF	16V	
C3	CS15E1C4R7M	T	4.7μF	16V	
C4	CS15E1VOR1M	T	0.1µF	35V	
_	E40-0373-05	Mini con	nect wafer	3P	
-	E40-0973-05	Mini con	nect wafer	9P	
_	N09-0625-04	Screw	,	M2.5 × 6	.:
-	N14-0520-04	Nut	1	M2.5	₩:
D1	V11-7272-36	LED		PR5532K	
D2	V11-7272-46	LED		PY5532K	-
D3	V11-7272-36	LED	1	PR5532K	
D4	V11-7272-46	LED	1	PY5532K	-
D5	V11-7272-36	LED	1	PR5532K	Ì
D6	V11-3173-06	LEO		TLR4135	*
D7	V11-3172-96	LED	•	TLR323	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
08	V11-3173-16	LED bloc	k	TLM8051	÷
Ω1	V30-1163-06	ıc		LB1409	☆

RX UNIT (X55-1270-XX) XX: 10(K), 51(T), 61(W)

Ref. No.	Parts No		Description	1	Re- marks
C1	CC45RH1H12OJ	С	12pF	±5%	
C2	CC45CH1H330J	С	33pF	±5%	1
C3	CC45CH1H030C	C	3pF	±0.25pF	
C4	CC45CH1H220J	С	22pF	±5%	1 1
C5	CC45RH1H100D	С	10pF	±0.5pF	1 1
C12	CC45CH1H330J	С	33pF	±5%	
C13	CC45CH1H020C	c	2pF	±0.25pF	1 1
C14	CC45CH1H150J	С	15pF	±5%	1
C15	CC45CH1H0R5C	С	0.5pF	±0.25pF	1 1
C18	CC45CH1H050C	С	5pF	±0.25pF	
C19	CC45CH1H680J	С	68pF	±5%	1
C20	CQ92M1H223K	ML	0.022µF	±10%	1 1
C21	CQ92M1H103K	ML	0.01 _# F	±10%	
C23	CC45SL1H151J	С	150pF	± 5%	
C25	CC45CH1H220J	C	22pF	±5%	
C26	CE04W1A470Q	E	47µF	10V	
C28	CQ92M1H223K	ML	$0.022 \mu F$	±10%	
C29 ·	CE04W1A470Q	Ε	47µF	10V	
C32.33	CQ92M1H223K	ML	0.022µF	±10%	
C36	CE04W1A101Q	Ε	100µF	10V	
C37	CQ92M1H223K	ML	$0.022 \mu F$	±10%	
C38	CC45SL1H470J	С	47pF	±5%	1
C41	CQ92M1H222K	ML	0.0022µF	±10%	
C44	CQ92M1H222K	ML	0.0022µF	±10%	1
C45	CQ92M1H473K	ML	0.047µF	±10%	
C46	CQ92M1H223K	ML	0.022µF	±10%	

}

Ref. No.	Parts No.		Description	1	Re- marks	Ref. No.	Parts No.	Desci	iption	ma
	CQ92M1H102K	ML	·¹~0.001μF	±10%			CE04W1A470Q	E 47μF	100	
47		ML	0.0033µF	±10%			CE04W1C220Q	E 22µF	16V (W) (T)	
48	CQ92M1H332K	ML	0.0022µF	±10%		C148	CE04W1H010Q	E 1μF	50V (W) (T)	
49	CQ92M1H222K	1	•	±10%		C149.150	C91-0433-05	Laminated cap.	0.0039 _µ F (W) (T)	
50	CQ92M1H393K	ML	0.039μF			C151	CQ92M1H472K	ML 0.004	$7\mu F \pm 10\% (W) (T)$	
51	CQ92M1H222K	ML	0.0022µF	±10%		C152	C91-0433-05	Laminated cap.	0.0039µF(W)(T)	1
52	CQ92M1H103K	ML	0.01µF	±10%			CS15E1A150K	T 15μF	10V (T)	
53	CQ92M1H393K	ML	0.039µF	±10%		C153.154	CSISEIAISON	104.		
54	CS15E1VOR1M	Т	0.1µF	35V	1					1
55	CC45SL1H220J	c	22pF	±5%						
	CQ92M1H222K	ML	0.0022µF	±10%		TC1	C05-0062-05	Ceramic Trimmer		
256	CS15E1A3R3M	T	3.3µF	10V		TC2	C05-0030-15	Ceramic Trimmer		1
57.58		Т	4.7μF	16V		TC3	C05-0031-15	Ceramic Trimmer	10PF	
59	CS15E1C4R7M	1			1 1					
60	CQ92M1H223K	ML	0.022µF	±10%						
61	CQ92M1H473K	ML	0.047µF	±10%			E23-0046-04	Square terminal ×	: 7	
62	CE04W1C220Q	E	22μF	16V		-		Round terminal ×		
63	CE04W1C100Q	Ε	10µF	16V		-	E23-0401-05			
64	CQ92M1H103K	ML	0.01 µF	±10%	1	-	E40-0273-05	Mini connect waf		1
65	CS15E1VOR1M	T	0.1µF	35V			E40-0773-05	Mini connect waf		
	CQ92M1H332K	ML	0.0033µF	±10%		_	E40-0873-05	Mini connect waf		1
66		C	100pF	±5%		_	E40-1273-05	Mini connect waf	er 12P	
67	CC45SL1H101J		•	±10%						1
268	CQ92M1H332K	ML	0.0033µF	_	1			•		:
C69	CE04W1H010Q	E	1μF	50V			J31-0502-04	PC Board collar ×	6	
070	CE04W1A101Q	E	100µF	10V		1-	J42-0404-05	PC Board bush ×		1
C72	C90-0820-05	Ε	470µF	16V (small)		-	1342-0404-05	T C DOGIO DOGIT A	-	i
273	CE04W1A470Q	E	47µF	10V	1	1 .				,
C74	CC45SL1H101J	c	100pF	±5%				1_		1
	CE04W1A101Q	E	100µF	10V		L1.2	L31-0267-05	Tuning coil		1
275		ML	0.1μF	±10%		L3	L79-0452-05	Helical block	2 MHz (W)(T)	1
276	CQ92M1H104K			50V		L3	L79-0461-05	Helical block	5 MHz (K)	
:77	CE04W1H010Q	ε -	1μF			L4	L30-0289-05	IFT		-
278	CE04W1A101Q	E	100µF	10V	1	L5	L34-0683-05	Tuning coil		i
080	CE04W1C220Q	Ε	22µF	16V				IFT		-1
C86	C90-0820-05	E	470µF	16V (small)		L6	L30-0289-05		SFE 10.7 MA5	:
C87.88	CE04W1A470Q	E	47µF	10V		L7	L72-0014-05	Ceramic filter		
C89	CE04W1C470Q	E	47µF	16V		L8	L77-0858-05	Crystal	10.240 MHz	
		E	47µF	10V		L9	L40-1511-03	Ferri-inductor	150µH	
C90	CE04W1A470Q	T	1μF	16V	1	L10	L72-0315-05	Ceramic filter	CFW455F	E
C93	CS15E1C010M	1		25V		L11	L30-0504-05	: IFT		
C94	CE04W1E4R7Q	Ε	4.7μF			L12	L30-0503-05	1FT		
C95	CQ92M1H682K	ML	0.0068µF	±10%	,	1 1	L79-0446-05	Ceramic discri	CFY455S	
C96	CQ92M1H472K	ML	0.0047µF	±10%		L13		Ferri-inductor	6.8 mH	1
C97	CE04W1C220Q	E	22µF	16V ·		L14	L40-6825-04		J	-
C98	CE04W1A470Q	E	47µF	1 0V	i	L15	L15-0016-05	Choke trans.	150mH	i
C100	CE04W1H010Q	E	1µF	50V		L16	L40-1541-27	Ferri-inductor	150mH	
	CE04W1E4R7Q	E	4.7μF	25V	ė.	L17	L33-0615-05	Choke coil		
C101		1		10V	1	L18	L77-0859-05	Crystal	10.695 MHz	;
C102	CE04W1A470Q	E	47μF		Ī	L19	L40-1021-03	Ferri-inductor	1 mH	
C103	CQ92M1H103K	ML	0.01µF	±10%	1		L30-0005-05	IFT		- :
C104	CQ92M1H393K	ML	0.0 3 9μF	±10%	i	L20		Tuning coil		- 1
C106	CC45TH1H080D	С	8pF	±0.5pF	į	L21	L31-0313-05	-	10μH	,
C107	CC45UJ1H010C	c	1pF	±0.25pF		L22	L40-1001-03	Ferri-inductor	ΙΟμίτ	
	1 CC45SL1H221J	C	220pF	±5%		L23	L34-0886-05	Tuning coil		i
	CC45CH1H100D	C	10pF	±0.5pF		L24	L31-0180-05	Tuning coil		1
C112				±5%		L25	L31-0266-05	Tuning cail		
C114	CC45CH1H180J	C	18pF		İ	L26	L31-0267-05	Tuning coil		
C115	CC45CH1H33OJ	C	33pF	±5%		1 1	L40-1511-03	Ferri-indudor	150µH	
C116.11	7 CC45CH1H22OJ	C	22pF	±5%		L27		VHF coil	5ø5T	
C122	CC45TH1H020C	C	2pF	±0.25pF		L28	L34-0902-05		3φ6T	
	4 CC45TH1H100D	c	10pF	±0.5pF		L29	L34-0452-05	VHFcoil		
	CC45CH2H070D	C	7pF	±0.5pF		L30	L34-0691-05	VHF coil	5φ5T	
C125				±0.25pF	1	L31	L40-1021-03	Ferri inductor	1 mH	
C126	CC45TH1H030C	C	3pF			L32.33	L40-1011-03	Ferri-inductor	100µH	
C127.12	28 CC45TH1H060D	C	6pF	±0.5pF		1 232.33	1.0.0			
C129	CC45TH1H050C	C	5pF	±0.25pF						
C130	CC45TH1H060D	С	6pF	±0.5pF				1465	10 GOE MU-	
C131	CC45TH1H050C	C	5pF	±0.25pF		XF.(A.B)	L71-0216-05	MCF	10.695 MHz	
			22pF	±5%						
C132	CC45CH1H22OJ	C		_ 3 /6	1					
C138	C90-0804-05	C	0.001μF			VR1	R12-3025-05	Trim. pot	1 OkΩ	
C140	C90-0804-05	C	0.001µF	_		1 1	R12-1403-05	Trim. pot	1k!?	
C141	CC45CH1H100D	С	10pF	±0.5pF	1	VR2	1		5kΩ	
	44 CC45CH1HOR5C	C	0.5pF	±0.25pF		VR3	R12-2015-05	Trim. pat	VI	_

For Service Manuals Contact
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Email: enquiries@mauritron.co.uk

TR-7800

PARTS LIST/KEY BOARD ASSEMBLY

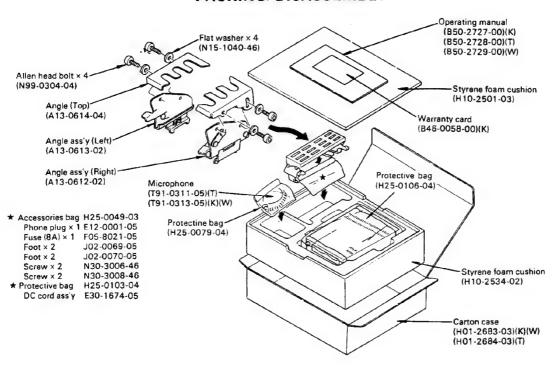
Ref. No.	Parts No.	Des	cription	Re- marks
VR4	R12-0042-05	Trim. pot	500Ω	
VR5	R12-2405-05	Trim. pot	5kΩ (W) (T)	
VR6	R12-4020-05	Trim. pot	50kΩ (2 pole) (T)	
-	R92-0150-05	Short jumper		
R 94	RC05GF2H560J	Solid	56Ω ±5% 1/2W	
R132	R92-0616-05	Metal film	10kΩ (W) (T)	
R133	RN14BK2E4703F	Metal film	470k $Ω ± 1%1/4$ W	
R137	R92-0616-05	Metal film	10kΩ (W) (T)	
R140	R92-0617-05	Metal film	7.5kΩ (W) (T)	
01.2	V09-1002-56	FET	3SK74 (L)	
Q3~11	V03-0079-05	TR	2SC460 (B)	
Q12.13	V03-1775-06	TR	2SC1775 (E)	
Q14~16	V03-1815-06	TR	2SC1815 (Y)	
Q17	V01-1015-06	TR	2SA1015 (Y)	
Q18.19	V03-1815-06	TR	2SC1815 (Y)	
Q20	V30-1045-06	IC	HA1366W	
021	V30-1135-06	IC	FS7808C	İ
022		Not used		
Ω23	V01-0113-05	TR	2SA496 (Y)	
024	V03-0336-05	TR	2SC496 (Y)	
Q25.26	V03-1815-06	TR	2SC1815 (Y)	
Q27	V30-1135-06	IC	FS7808C	1
Q28	V01-1015-06	TR	2SA1015 (Y)	
Q29	V03-2240-06	TR	2SC2240 (GR)	
Q30	V30-0039-05	IC	TA7061AP	
Q31.32	V03-0079-05	TR	2SC460 (B)	
Q33.34	V09-1014-06	FET	2SK61 (GR)	
Ω35	V09-1002-56	FET	35K74 (L)	1
Q36 Q37.38	V03-2538-16 V03-0093-05	TR TR	2SC2538-22-A 2SC458(B) (W)(T)	
D1.2	V11-0051-05	Diode	1N60	
D3~6	V11-0076-05	Diode	1\$1555	
D7~10	V11-0051-05	Diode	1N60	
D11	V11-1252-06	Varistor	151212	
D12	V11-0076-05	Diode not used	1S1555	
D13	V11-0076-05	Diode	1S1555	
D15	V11-4163-56	Zener diode	XZ-088	
D15	V11-0076-05	Diode	1S1555	
D17	V11-4101-20	Zener diode	XZ-060	
D18	V11-4162-66	Zener diode	XZ-070	
D19	V11-0219-05	Diode	V06B	1
D20.21	V11-0317-05	Vari-cap diode	1S2208	
D22~24		Vari-cap diode	ITT410	
D25	V11-0076-05	Diode	1S1555	
D26	V11-0076-05	Diode	1S1555 (W) (T)	
D27	V11-0076-05	Diode	1S1555 (T)	1

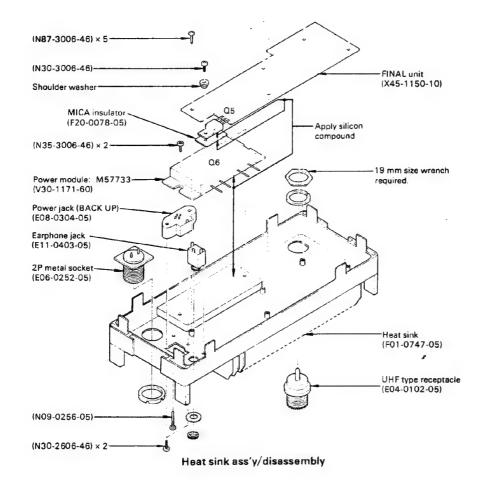
Key board ass'y (\$59-0406-05) Віз Во Вı Вг Вз G **(+)** 2 3 1 E3 0 Z 15:55 4 S (5) 6 Θ 7 8 9 B12 0 0 0 SC M

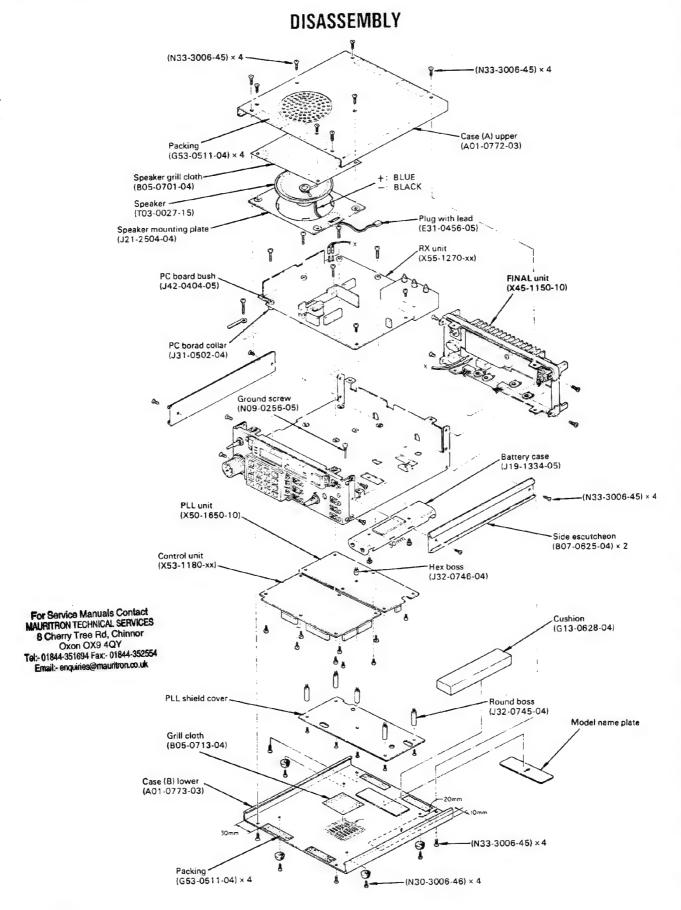
For Service Manuals Contact
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Oxon OX9 4QY
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PACKING/DISASSEMBLY

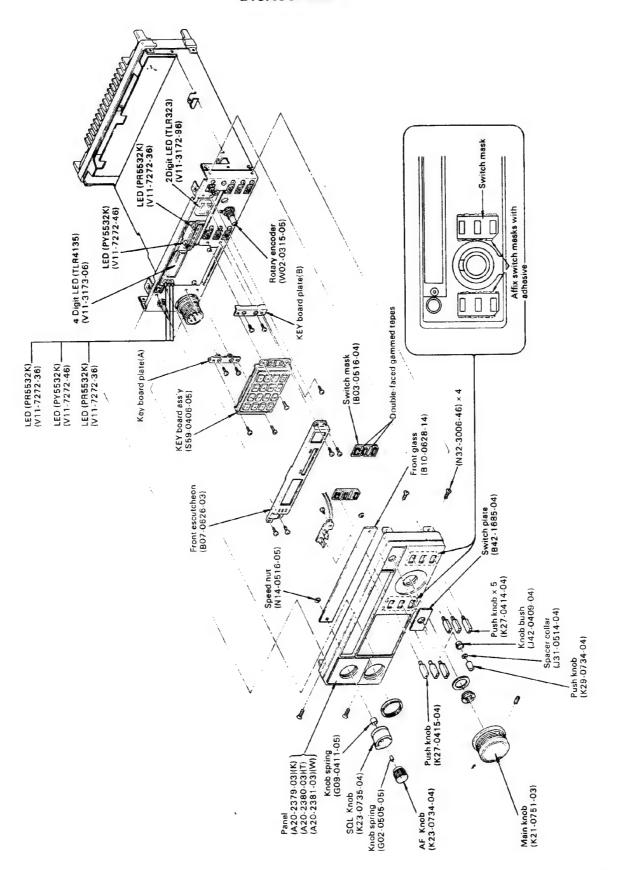
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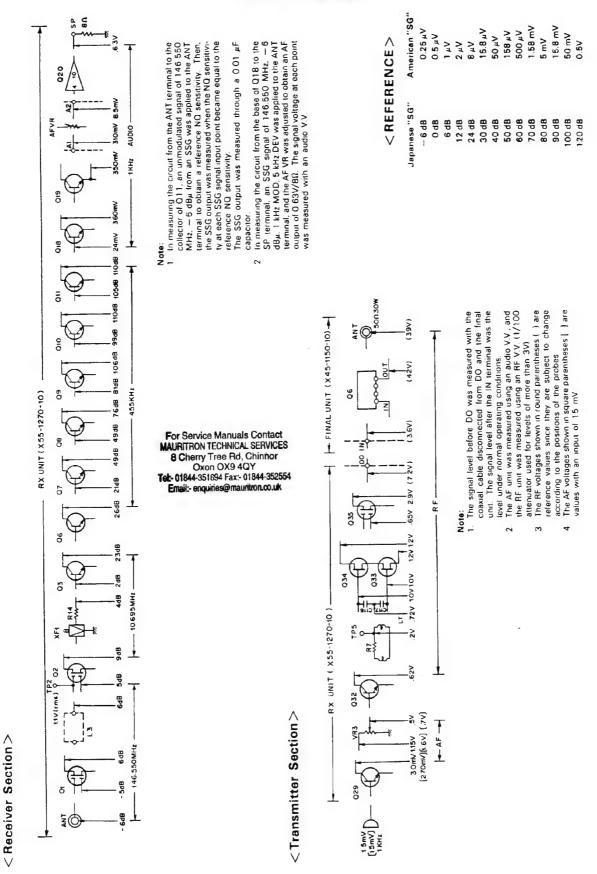




DISASSEMBLY



LEVEL DIAGRAM



<Test Equipment>

1. Tester

Input: Sufficient

2. RF VTVM (RF V.M.)

ullet Input impedance: 1 M Ω and less than 2 pF

• Voltage range: F.S. = 10 mV to 300V

• Frequency range: 150 MHz or greater

3. Frequency counter (F count)

Minimum input voltage: 50 mV

Frequency range: 150 MHz or greater

4. DC power supply

Voltage 10V to 17V variable

Current: 6A min.

5. RF Power Meter

Dissipation: 20W

ullet Impedance: 50Ω

Frequency range: 144 MHz

6. AF VTVM (AF V.M.)

 \bullet Input impedance: 1 $M\Omega$ or greater

Voltage range: F.S = 1 mV to 30V

Frequency range: 50 Hz to 10 kHz

7. AF Generator (AG)

• Frequency range: 100 Hz to 10 kHz

• Output: 0.5 mV to 1V

8. Linear detector

• Frequency range: 144 MHz

9. Directional coupler

10. Oscilloscope

With horizontal input and high sensitivity

11. Standard signal generator (SSG)

• Frequency range: 144 ~ 149 MHz

Modulation: amplitude and frequency modulation

• Output: $-20 \text{ dB} \sim 100 \text{ dB}$

12. AF Dummy load

8Ω, 5W (approx.)

13. Sweep generator

j

• Frequency range: 144 ~ 149 MHz

< Preparation >

Unless otherwise specified, set the controls as follows.

POWER/VOL SW SEND/REC (MIC) AF VOL SQUELCH VOL KEY M. SEL SW STEP SW HI/LOW SW PRIORITY { ALERT OPER	ON REC MIN MIN KEY 10 kHz HI OFF
TONE	OFF

Notes:

- When adjusting the trimmers or coils, use a non-induced adjusting rod of bakelite, etc.
- When adjusting the RX section never transmit to prevent SSG damage.
- Connect MIC connector as shown in Fig. 18.

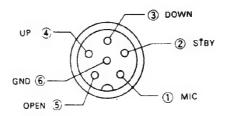


Fig. 17 MIC terminals (view from front panel side)

The output level of SSG is indicated as SSG's open circut.

For Service Manuals Contact
MAURITRON TECHNICAL SERVICES
8 Cherry Tree Rd, Chinnor
Oxon OX9 4QY
Telt-01844-351694 Fax:- 01844-352554
Email:- enquiries@mauritron.co.uk

RX UNIT (X55-1270-10) ADJUSTMENT

[TX]

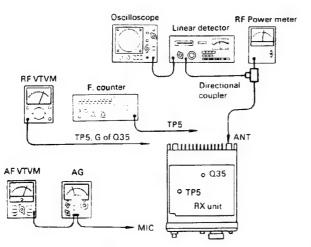
- 1. 10.695 MHz
 - Unplug the LT connector. Place the unit in transmit mode.

٠,١,

- Connect RF VTVM to TP5 and adjust L20 and L21 for the maximum signal (0.21V rms nominal)
- Connect frequency counter to TP5 and adjust TC1 for 10.6950 MHz.
- 2 VCT circuit
 - Connect the LT connector. Adjust the dial frequency to 147,000. Set VR4 to the centerposition and TC2 to the minimum position. Unplug the DO terminal.



TC2 Minimum position



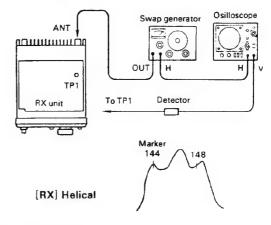
[TX] 10.695 MHz, VCT, Drive, Deviation

- Connect RF VTVM to Q35 (3SK74) G1 and place the unit in transmit mode.
- Adjust L23, L24, L25 and L26 for maximum signal. Repeat twice. Nominal reading is 0.8V ±0.1.
- 3. Drive adjustment
 - 1) Connect the DO terminal and transimt at 147,000.
 - Adjust TC2 and TC3 for maximum current drain (approx. 31W).
 - Using a spectrum analyzer, adjust VR4 for minimum ±10.7 MHz spurious, (VR4 adjusting range: 11 o'clock).
- 4 Deviation adjustment
 - 1) Connect to a linear detector.
 - Set frequency to 147.000 in transmit mode and apply a signal of 1 kHz, 40 mV to the MIC terminal.
 - 3) Adjust VR3 for 5.0 kHz of deviation.
 - Adjust the AG output level for 3.5 kHz deviation. Check that it is less than 4 mV.

[RX]

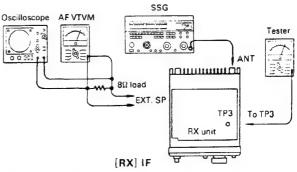
- 1. Helical adjustment
 - 1) Connect to a sweep generator.
 - 2) Unplug the LR connector (any frequency).
 - Adjust L1, L2 and L3 to obtain the waveform shown below

(adjust so the 144.0 marker comes to the edge of the helical waveform)

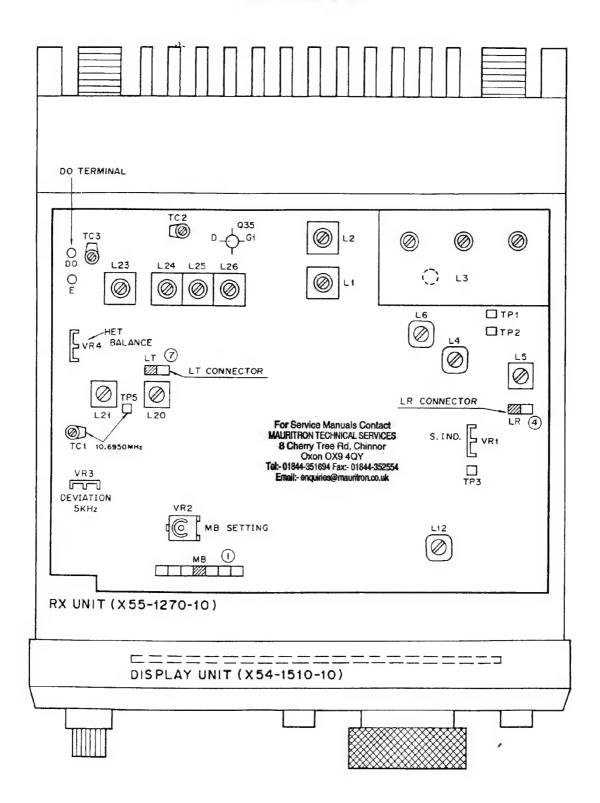


2. IF adjustment

- Connect a DC voltmeter, 3V range, to TP3 Reconnect the LR terminal.
- Set frequency to 146.100 and adjust SSG for 10 dBμ output (1 kHz, 5 kHz dev.).
- Adjust L5, L4 and L6 for a maximum meter indication.
- Adjust L12 for maximum AF output with best waveform.

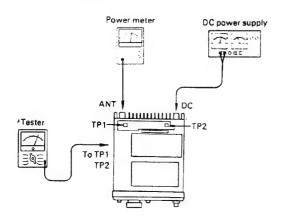


- 3. MB voltage adjustment
 - Connect a DC voltmeter. 6V range, to the harness connector MB terminal. Turn the volume control power SW OFF.
 - 2) Adjust VR2 for 5.2V.
- LED meter adjustment (RX)
 - 1) Set SSG to 0 dB μ and adjust VR1 so that one LED lights.
 - Check that all LEDs go off at -1 dBμ of SSG input.
 - 3) Check that 5 LEDs light at 20 dB μ (+10 dB, -2 dB) of SSG input.



FINAL UNIT (X45-1150-10) ADJUSTMENT

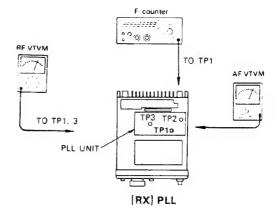
- Protection NULL adjustment (TXmode)
 - Set frequency to 147.000 MHz, HI/LO switch to HI power. Connect DC voltmeter (3V range) to TP1
 - Adjust VR2 for a minimum voltage (less than 0.7V).
- 2. High power output check (TX mode)
 - Set frequency to 147.000 MHz, HI/LO switch to HI power. Check that total current is less than 6.5A and output is greater than 28W.
 - 2) Check that output at the band edges (139.900 MHz and 148.995 MHz) is within ±2W of the output at 147.000 MHz and total current is less than 6.5A.
- 3. Low power output adjustment (TX mode)
 - Set frequency to 147.000 MHz, HI/LO switch to LO power. Adjust VR4 for 5W output ±0.5W.
 - Check that output at 143,900 MHz and 148,995 MHz is within ±1W for the output at 147,000 MHz.
- 3. LED meter adjustment (TX mode)
 - Set frequency to 147,000 MHz, HI/LO switch to HI. Adjust VR1 for all (5) LEDs ON.
 - Place the HI/LO switch to LO and check that 3 LEDs light (the two red LEDs go off).
- 4. Protection adjustment (TX mode)
 - Set frequency to 147,000 MHz, HI/LO switch to HI. Open the ANT terminal (disconnect the load).
 - 2) Connect a DC voltmeter (12V range) to TP2. With VR3 turned fully counterclockwise, the meter should indicate about 12V. Clockwise adjustment reduces the voltage from about 12V to 6V. Adjust VR3 clockwise approx. 60° from this point and check that the voltage is 5.0 6.0V and total current is less than 2.5A.



[TX] FINAL unit, Protection

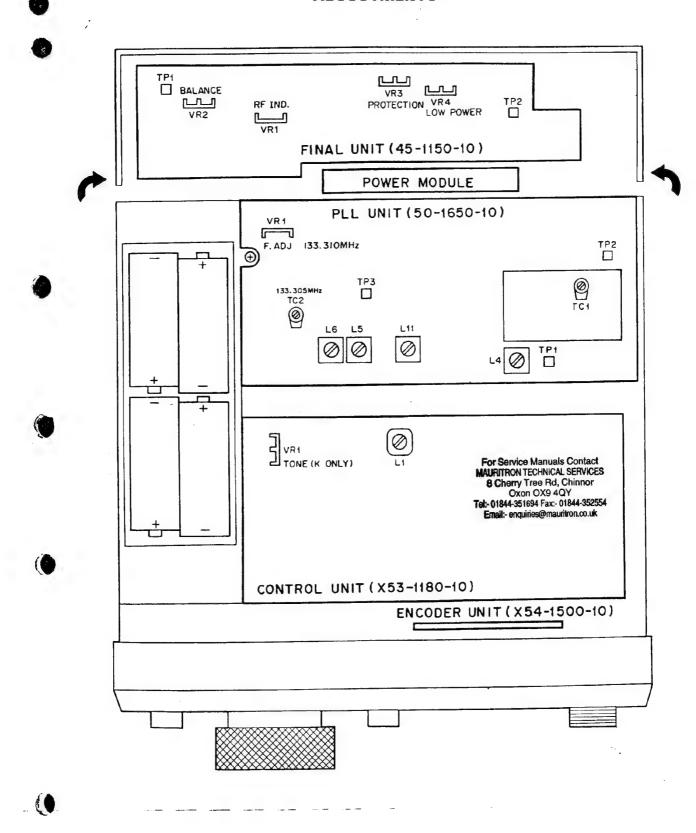
PLL UNIT (X50-1650-10) ADJUSTMENT

- 1. IF adjustment (RX mode)
 - Set frequency to 148.995 MHz and connect RF VTVM to TP3.
 - Adjust L11, L6 and L5 for maximum (greater than 0.5V).
- 2. Lock voltage adjustment (RX mode)
 - 1) Set frequency to 148.995 MHz and connect a DC voltmeter to TP2.
 - Adjust TC1 in the VCO shielded compartment to 7.0V.
 - 3) Reset frequency to 144,000 MHz and check that the voltage at TP2 is greater than 1.9V.
- 3. Output adjustment (TX mode)
 - Set frequency to 147,000 MHz and connect an RF VTVM to TP1.
 - 2) Adjust L4 for maximum signal (0.2V).
- 4. Frequency adjustment (RX mode)
 - 1) Set frequency to 144,000 MHz and connect a frequency counter to TP1.
 - 2) Adjust TC2 for 133.305 MHz ±100 Hz. ...
 - 3) Reset frequency to 144,005 MHz.
 - 4) Adjust VR1 for 133.310 MHz ±100 Hz.



CONTROL UNIT (X53-1180-10) ADJUSTMENT K TYPE ONLY

- 1. Touch tone deviation adjustment (TX mode)
 - First perform the RX unit Deviation Adjustment in Item 4. After this adjustment, transmit and depress the "5" key.
 - 2) Adjust VR1 for 3 \sim 3.5 kHz deviation (L₁: Adjustment is not needed.)



OPERATIONAL CHECKS

- Depress the key.
 - 1) The orange ◀ LED will light.
 - 2) Enter frequency.
 - a) The 4-digit frequency display will indicate 3 8 MHz.

When the MHz digit is 3, only 9 should enter as a 100 kHz digit.

When the 0-4 key is pressed, 0 enters as the 1 kHz digit.

When the 5-9 key is pressed, 5 enters as the 1 kHz digit.

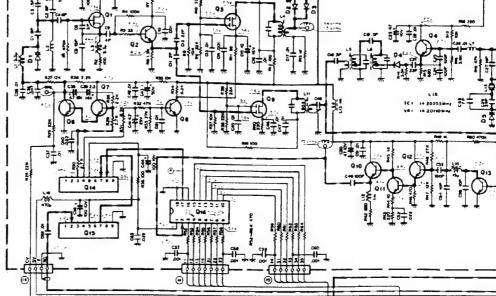
- After the full 4-digit frequency is entered, the yellow S (Simplex) LED will light.
- 3) Selecting the TX OFFSET mode.
 - a) The offset mode will enter when the "+"."-"
 or "S" keys are pressed between the frequency
 range of 4.000 to 7.995.
 - Only the S mode should enter above or below this range.
- 4) REV SW check
 - a) Set frequency to 4.500 and press the "+" key.
 - b) Press the REV key. The display should indicate 5.100 and the offset mode should indicate "+".
 - Release the REV key. The display should again indicate 4.500 "—".
 - d) Press the REV key. The display should indicate4.500, S. The beeper will sound.
- 5) "C" key check
 - a) The display should indicate 4.500 S.
 - b) Enter half frequency in the display.
 - c) Press the "C" key. The display should return to 4.500 S.
- 6) Memory channel selector check
 - a) Turn the memory channel selector to the right.
 The channel display will continuously count from 0 to 14 in endless sequence.
 - Turn the memory channel selector to the left.
 The channel display will count down from 14 to 0 in endless sequence.
- 7) "M" key check
 - a) When the memory channel selector is channel in 0 or 14 (K type) (channel 13 or 14 W type).
 - (1) Set frequency to 3.950.
 - (2) Press the "M" key. The beeper will pulse.
 - (3) Set TX frequency to 8.500.
 - (4) Press the "M" key again. The display will indicate 3.950 and the beeper will stop sounding.
 - b) When the memory channel selector is 0 channel 1 13 (K type) (channel 0 12 W type)
 - (1) Set frequency to 4.270 and TX offset to "+".
 - (2) Press the "M" key and the beeper will sound.
 - (3) Set frequency to 4.270 and the TX offset to "-"

- (4) The beeper will stop when the "M" key is pressed.
- 8) "SC" key check
 - a) Press the "SC" key. The radio will scan up continuously while the squelch is closed.
 - Open the squelch and the scan will stop momentarily. Scan will resume at approx. 6 second intervals.
 - Scan should release when the "C" key or PTT is pressed.
 - The scan step will change from 10 kHz to 5 kHz by using the STEP switch.
- 9) UP/DOWN check
 - a) Connect the UP/DOWN microphone. The radio will scan up by pressing the UP switch and down by pressing the DOWN switch. Scan will stop when both switches are depressed.
 - The scan up and down step is determined by the STEP switch.
- 2. Release the M. SEL _ key.
 - 1) The orange M. SEL ► LED will light.
 - 2) Turn the memory channel selector. The frequency set in item 1, 7) and TX mode will display.
 - 3) Priority alert switch check
 - a) Press the priority alert switch to open the squelch.
 - The beeper will sound at about 6 second intervals.
 - 4) Priority operate switch check
 - a) Press the priority operate switch and the channel display will indicate CH 0 (CH 14 for W type). The display will indicate the frequency set in item 1, 7.
 - This operation takes precedence over other functions (except during keyboard entry).
 - 5) REV will operate with any memory.
 - The SC (scan) will operate with frequencies stored in memory. All other functions are as outlined in item 1 — 8.
 - The scan will move up or down for the channel as selected by the UP/DOWN microphone switch.
- 3. Transmit mode checks.
 - 1) Touch tone encoder check.
 - a) Press the 1 9, 0, C, and M keys. The signal from the receive monitor should be two tone.
 - b) When two keys are pressed simultaneously, check that the signal from the receive monitor is A single tone.
- 4. Backup function check
 - a) Turn the power switch ON and OFF. Check that the display frequency is retained.
 - When the power switch is turned OFF and ON during scan, the scan should be released.
- 7.6V DC ±0.5V should be present at the battery case "+" terminal at power SW ON when battery is not "-loaded.

TR-7800

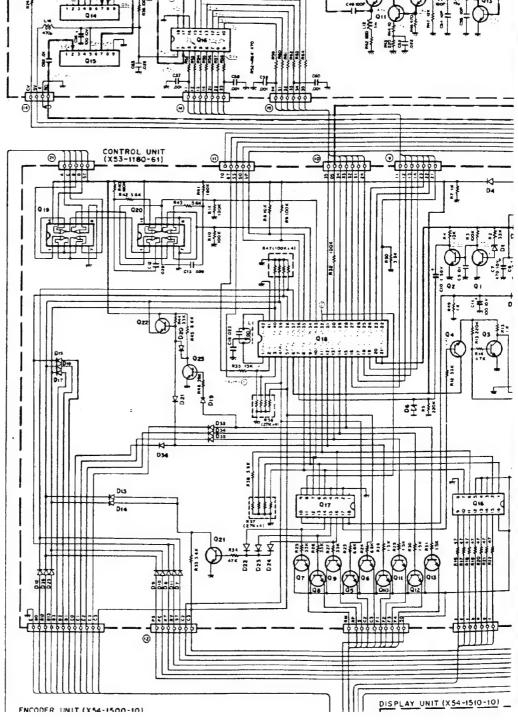
PLL UNIT (X50-1650-10)

SCHEMATIC DIAGRAM (W)

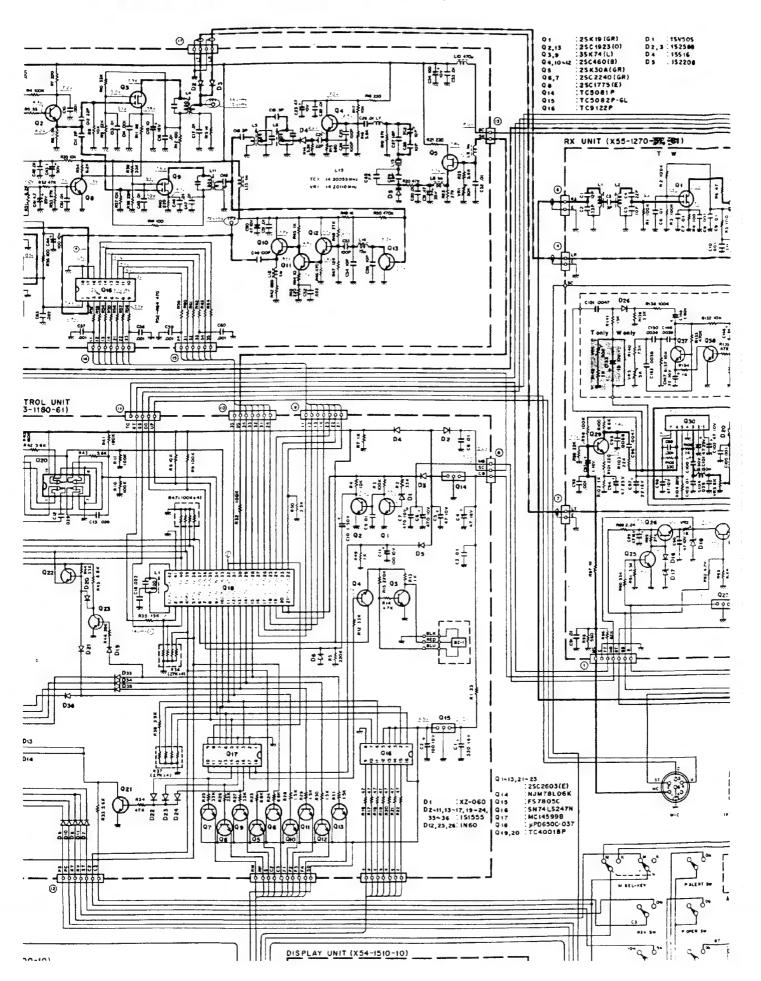


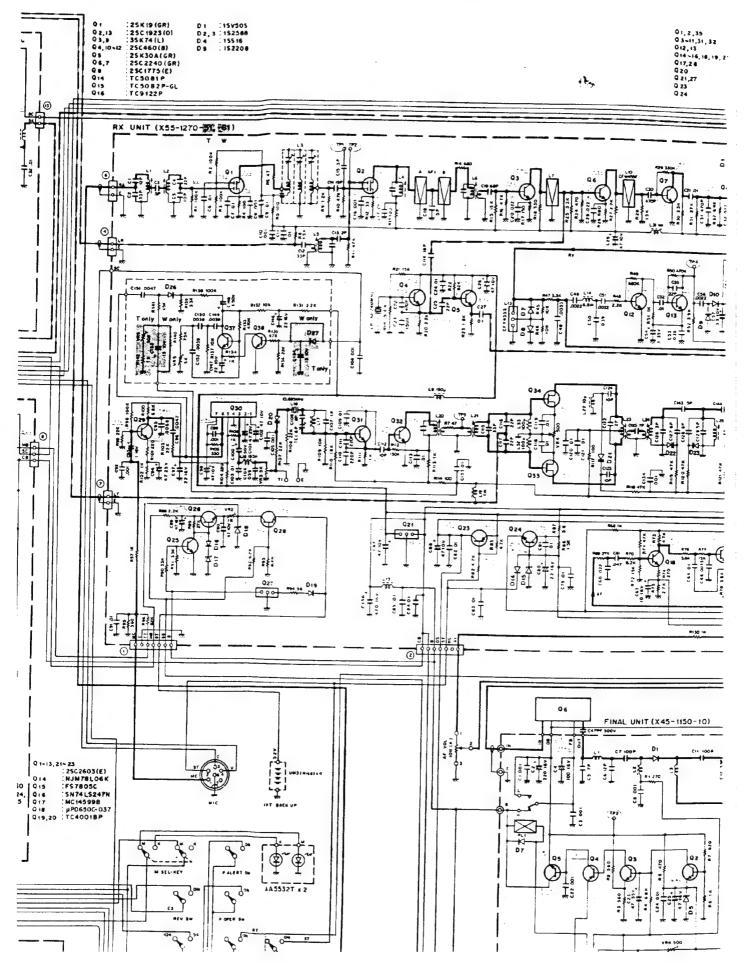
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8 Cherry Tree Rd, Chinnor
Oxon OX9 4QY
Tet: 01844-351694 Fax: 01844-352554
Email: enquiries@mauritron.co.uk

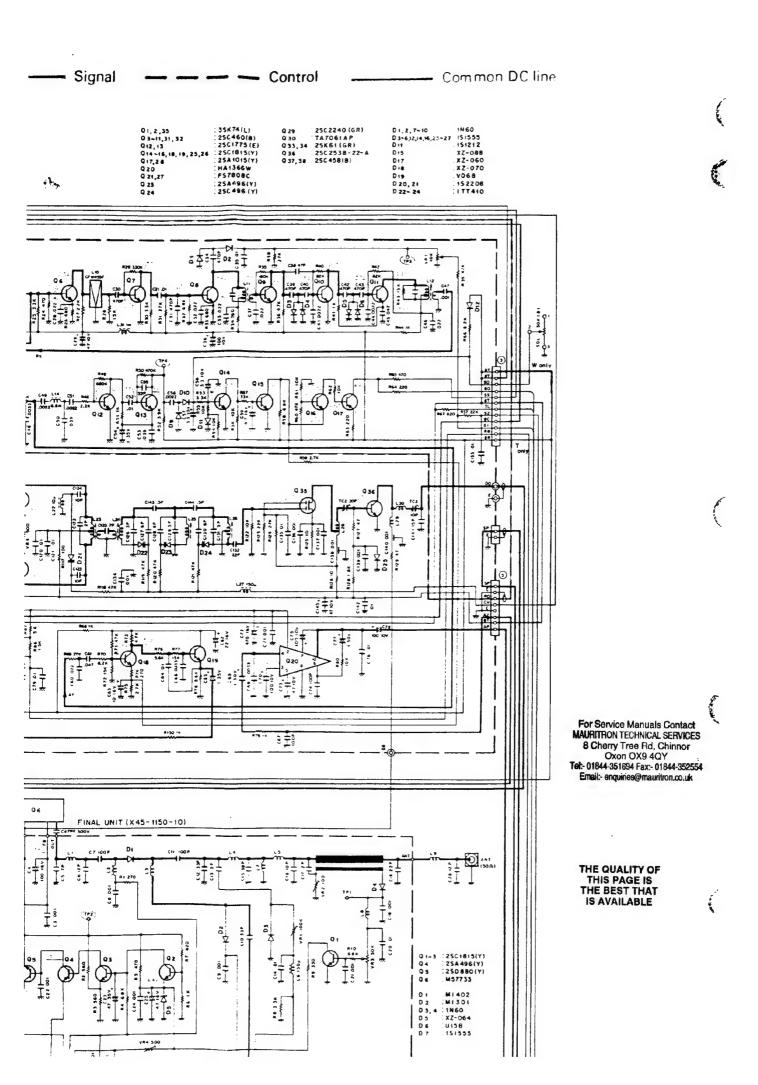
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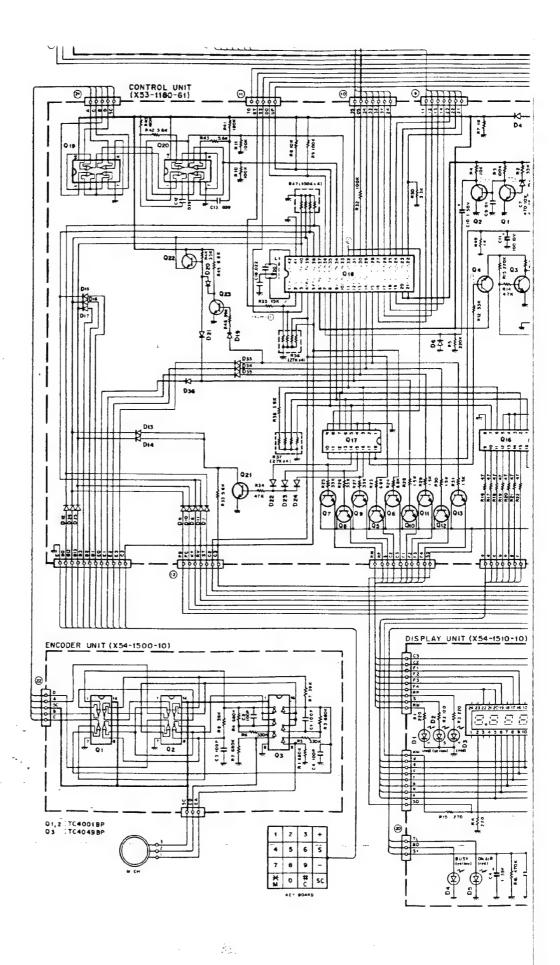


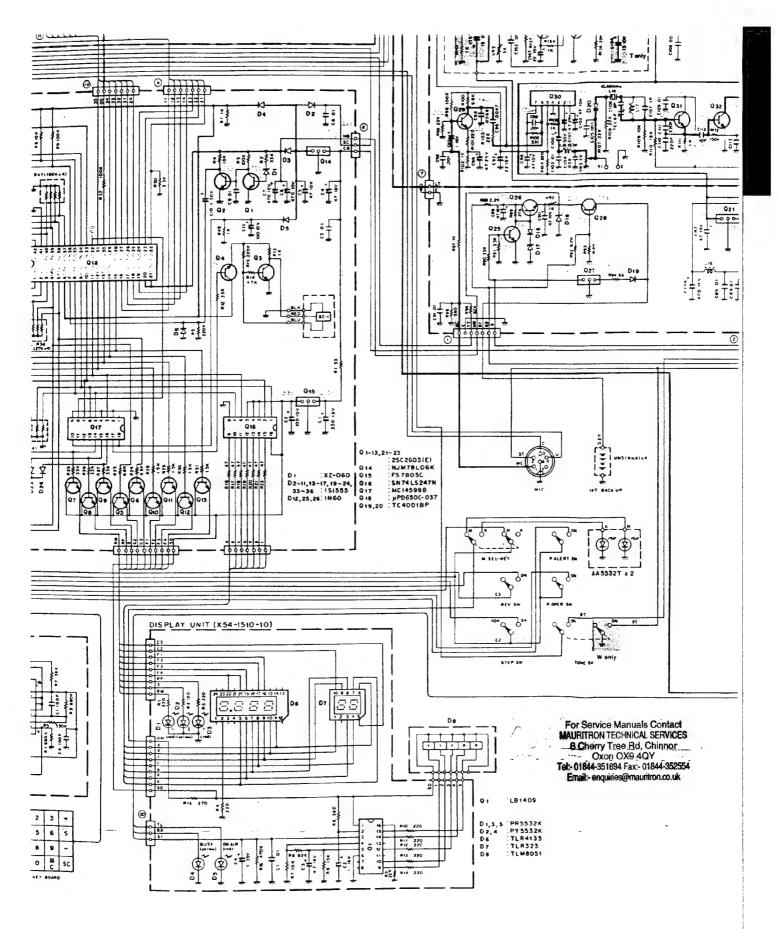
SCHEMATIC DIAGRAM (W) (T)



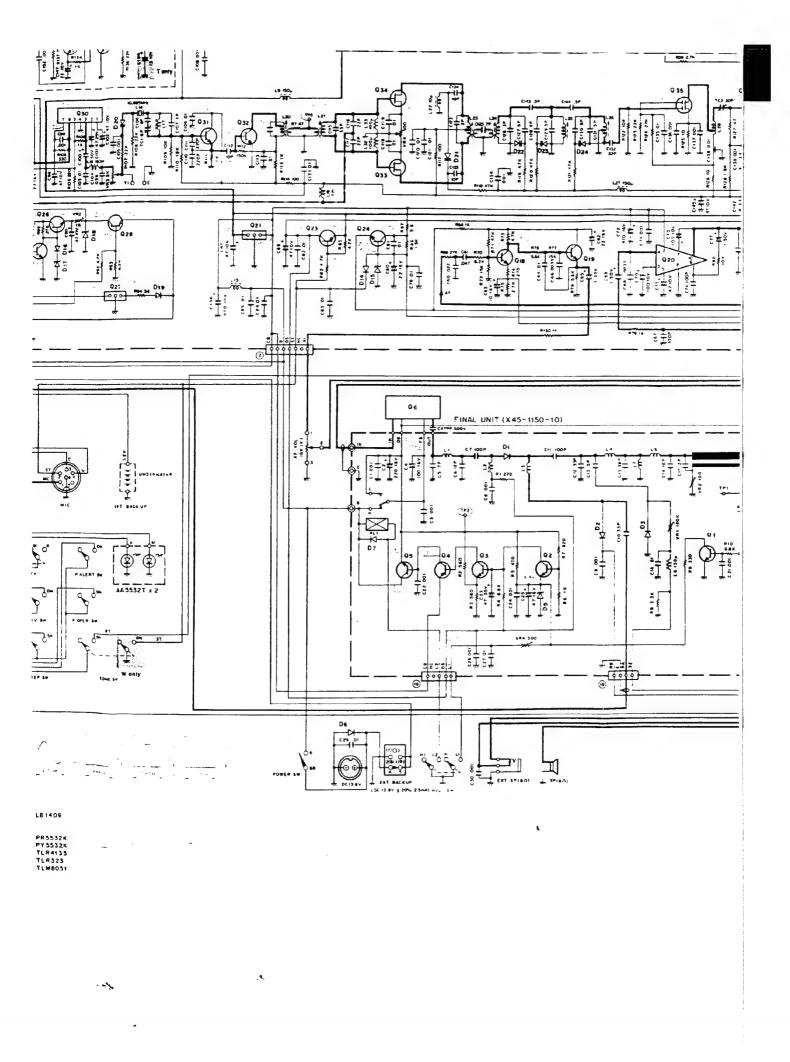


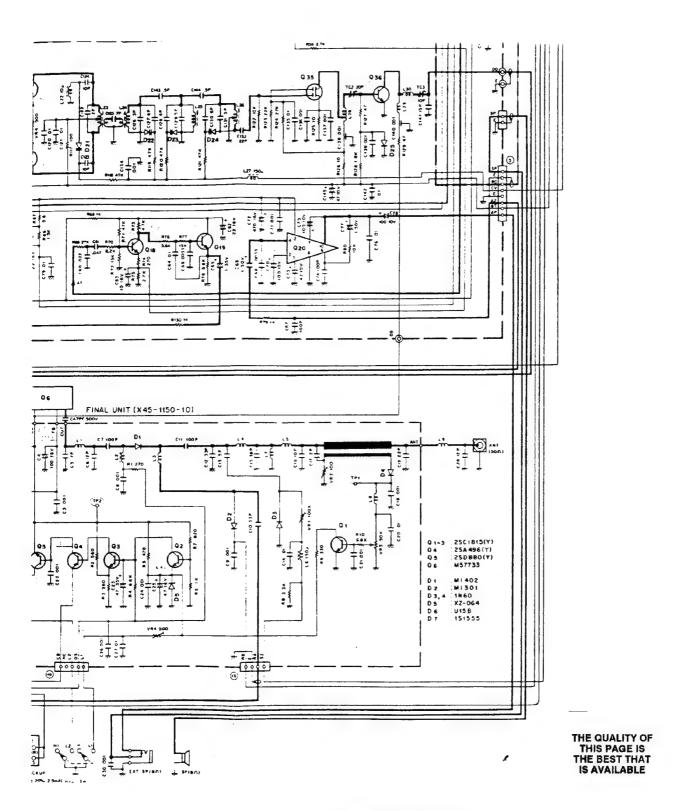






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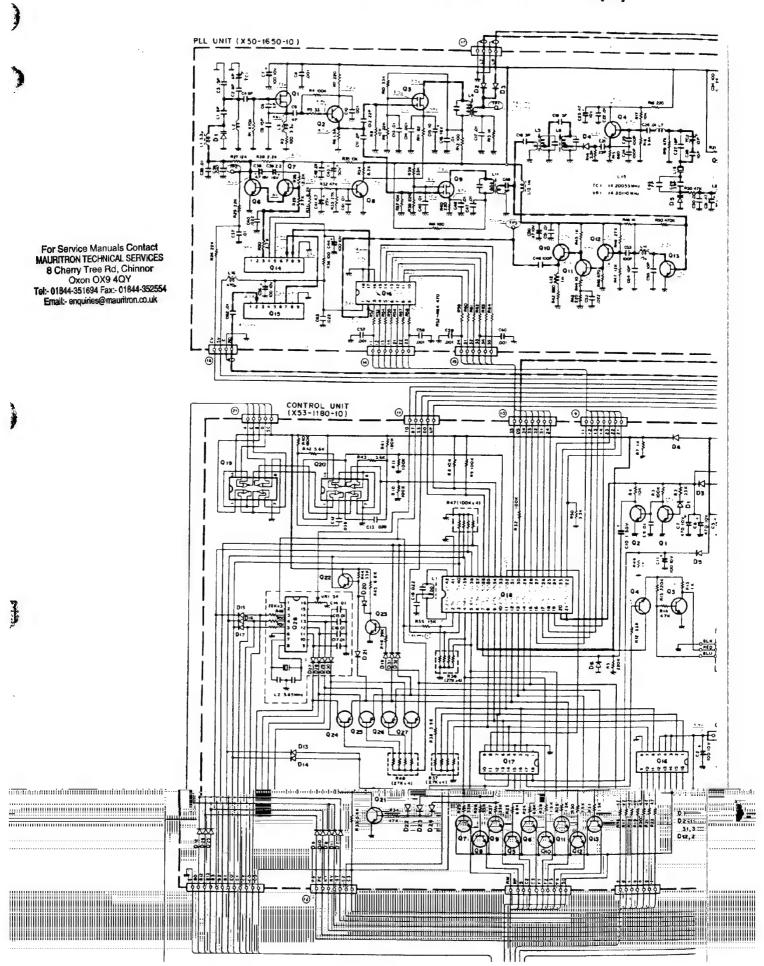


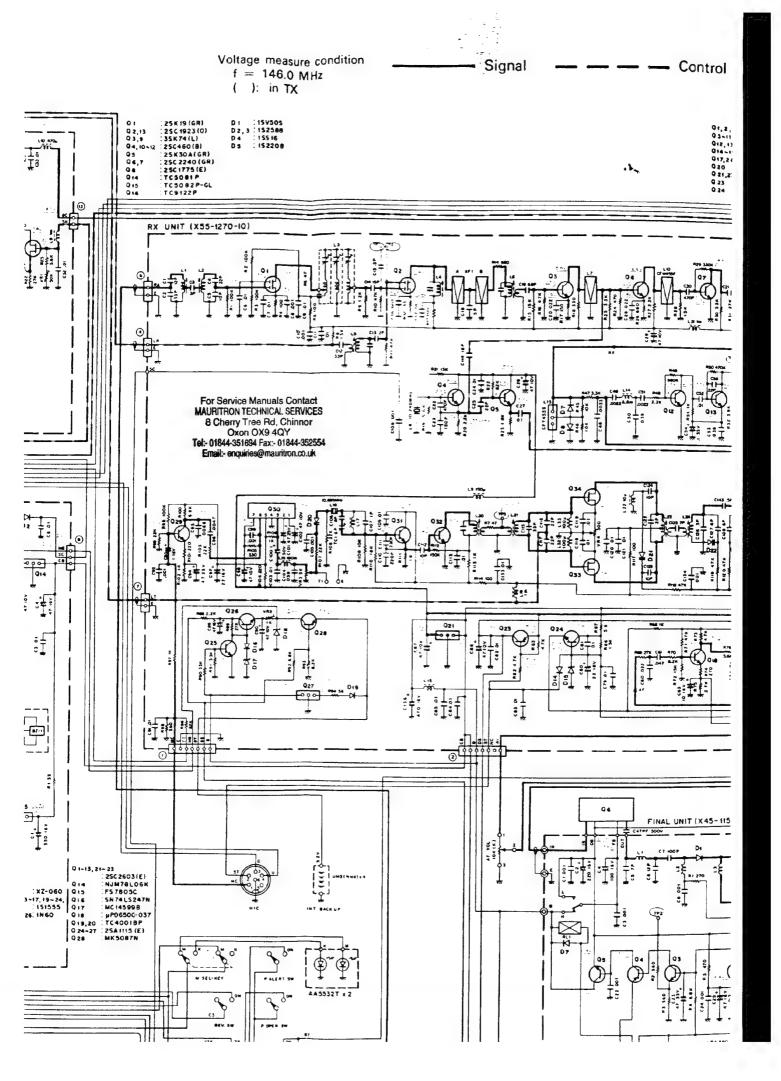


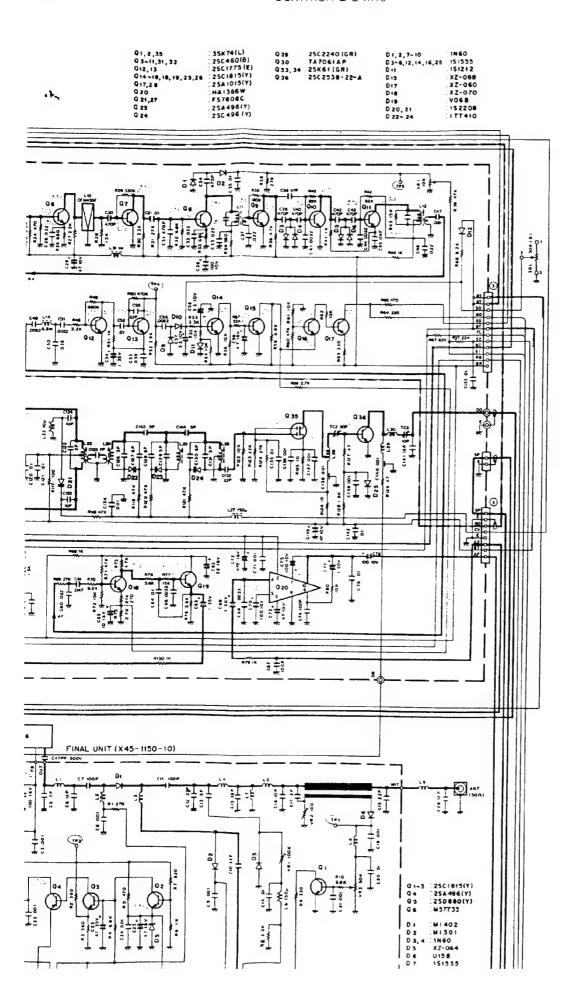
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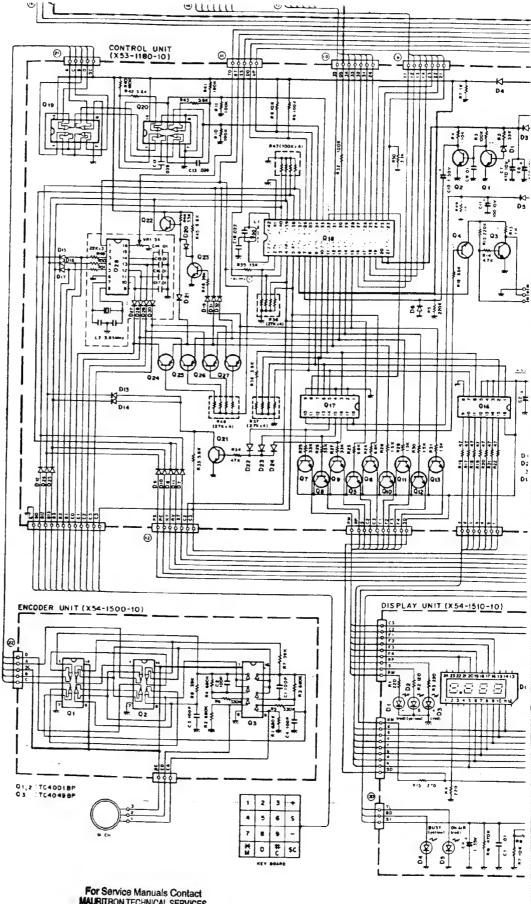
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SCHEMATIC DIAGRAM (K)

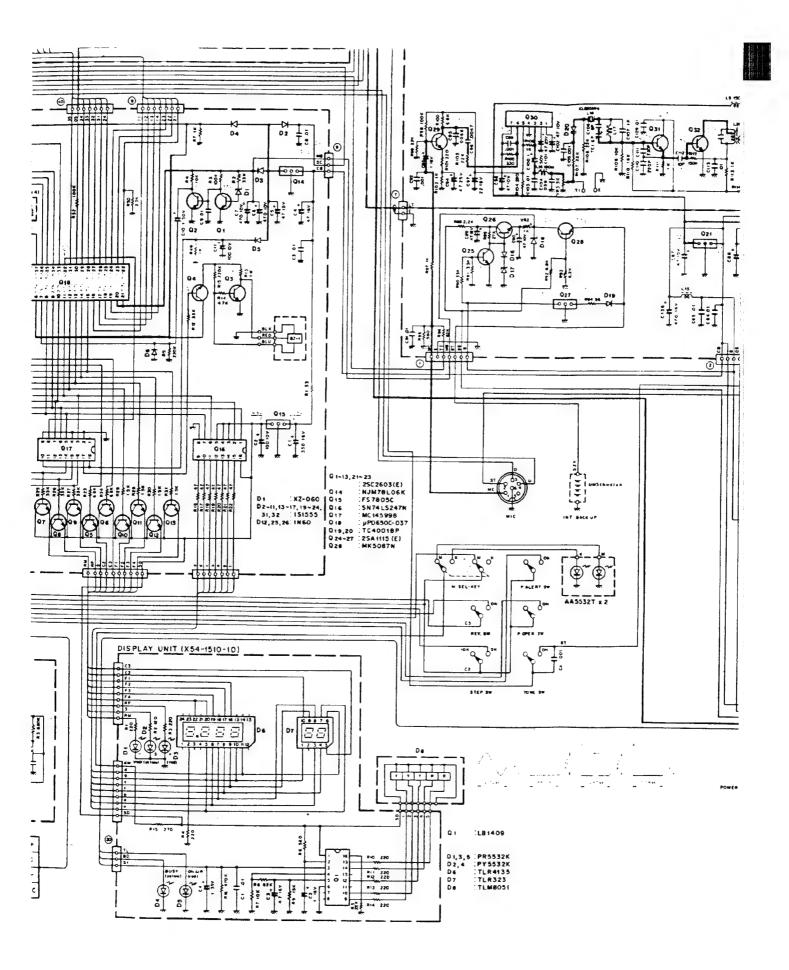




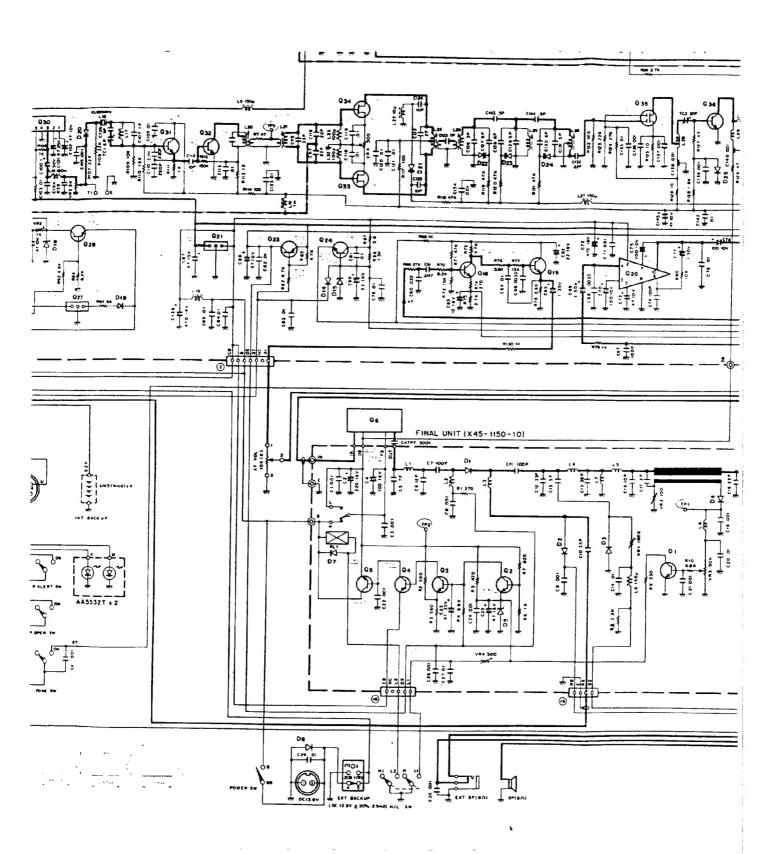




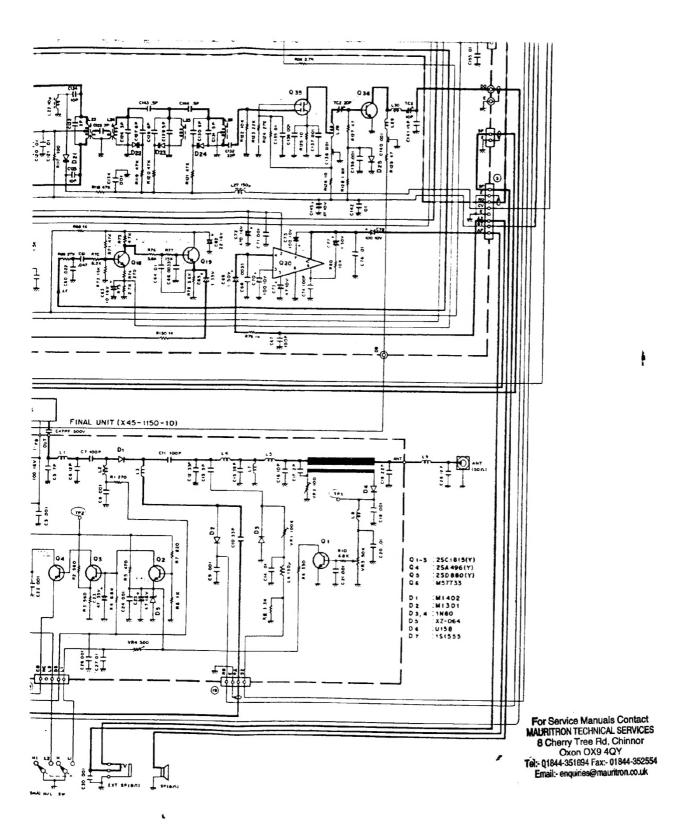
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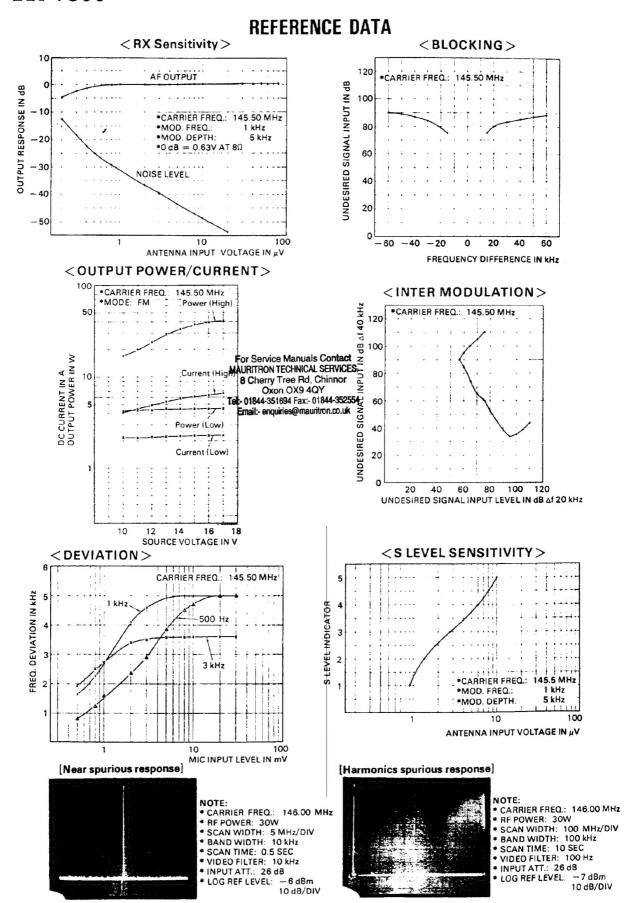
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TR-7800



SPECIFICATIONS

(K type)		(W, T type)	
General		General	
Semiconductors	. MPU 1		*****
	(Cs 19	Semiconductors	MPU 1 ICs 18
	Transistors 60		Transistors 58
	FETs 9		FETs 9
	Diodes 77		Diodes 78 (W), 79 (T)
Frequency range		Frequency range	
	Digital control, phase locked VCO		Digital control, phase locked VCO
Mode		Mode	
Antenna impedance		Antenna impedance	50 ohms
Power requirement		Power requirement	
Grounding		Grounding	Negative
Operating temperature	-20°C to +50°C	Operating temperature	-20°C to +50°C
Current drain	0.4A in receive mode with no input signal	Current drain	0.4A in receive mode with no input signal
	6.5A in HI transmit mode (Approx.)		6.5A in HI transmit mode (Approx.)
	3A in LOW transmit mode (Approx.)		3A in LOW transmit mode (Approtx.)
	Less than 3 mA for memory back up		Less than 3 mA for memory back up
	(from power supply)		(from power supply)
	Less than 2.3 mA for memory back up		Less than 2.3 mA for memory back up (from battery)
	(from battery)	Dimensions	
Dimensions		Dimensions	64 mm (2 — 1/2") high
	64 mm (2 - 1/2") high		206 mm (8-1/16") deep
	206 mm (8-1/16") deep		(Projections excluded)
Weight	(Projections excluded)	Weight	
AACIGIIC			
_		Transmitter Section	
Transmitter Section		Transmitter Section	
Transmitter Section RF output power		RF output power	LI 25 Watte min
Transmitter Section RF output power (at 13.8V DC, 50Ω load)	.HI 25 Watts min.	· · direction de de de de de de de de de de de de de	
Transmitter Section RF output power (at 13.8V DC, 50Ω load)	.HI 25 Watts min. LOW 5 Watts approx. (Adjustable)	RF output power (at 13.8V DC, 501 load)	LOW 5 Watts approx. (Adjustable)
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	.HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift	RF output power (at 13.8V DC, 50!} load)	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	.HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation Frequency tolerance(-20°C ~ +50°C)	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 × 10 ^{- 6}	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-16}$
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 × 10 ^{- 6}	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-16}$
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \cdot 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than - 60 dB LOW Less than - 53 dB	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation Frequency tolerance (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than $\pm 20 \cdot 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than - 60 dB LOW Less than - 53 dB	RF output power (at 13.8 V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than — 60 dB LOW Less than — 53 dB ±5 kHz 1.750 Hz (Burst): (T)
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 · 10 · 6 HI Less than — 60 dB LOW Less than — 53 dB ±5 kHz Dynamic microphone with PTT switch, 500Ω	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 · 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500th Double conversion superheterodyne 1st 1F = 10.695 MHz	RF output power (at 13.8V DC, 50:! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-5}$ HI Less than -60 dB LOW Less than -53 dB ± 5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch, 5009
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation Frequency tolerance (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500!! Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1,750 Hz (Burst): (T) Dynamic microphone with PTT switch, 5009 Double conversion superheterodyne
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation Frequency tolerance (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500\text{!} Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5µV for 30 dB S/N	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1,750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!: Double conversion superheterodyne 1st 1F = 10,695 MHz
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance. (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 · 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500\(\text{2}\) Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5 \(\text{LV} \) for 30 dB S/N Better than 0 2 \(\text{LV} \) for 12 dB SINAD	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!! Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance (-20°C \rightarrow +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity Receiver selectivity	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500Ω Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5µV for 30 dB S/N Better than 0 2µV for 12 dB SINAD More than 12 kHz (- 6 dB)	RF output power (at 13.8V DC, 50:! load) Modulation Frequency tolerance	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1,750 Hz (Burst): (T) Dynamic microphone with PTT switch, 5009 Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0.5µV for 30 dB S/N
Transmitter Section RF output power (at 13.8V DC, 50Ω load) Modulation Frequency tolerance (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity Receiver selectivity	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 × 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500!? Double conversion superheterodyne 1st 1F 10.695 MHz 2nd 1F 455 kHz Better than 0 5µV for 30 dB S/N Better than 0 2µV for 12 dB SINAD More than 12 kHz (- 6 dB) Less than 24 kHz (- 60 dB)	RF output power (at 13.8V DC, 50:! load) Modulation Frequency tolerance	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1,750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!: Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0.5µV for 30 dB S/N Better than 0.5µV for 12 dB SINAD
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance. (-20°C \times +50°C) Spurious radiation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 · 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500\(\frac{1}{2}\) Double conversion superheterodyne 1st 1F 10.695 MHz 2nd 1F 455 kHz Better than 0 5 \(\frac{1}{2}\) for 30 dB S/N Better than 0 2 \(\frac{1}{2}\) V for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 0 dB	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1,750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!: Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0.5µV for 30 dB S/N Better than 0.5µV for 12 dB SINAD
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance (-20°C ~ +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity Receiver selectivity Spurious response Squelch sensitivity	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 × 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500th Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5µV for 30 dB S/N Better than 0 5µV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 60 dB 0.16µV (threshold)	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB ± 5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!! Double conversion superheterodyne 1st 1F 10.695 MHz 2nd 1F 455 kHz 8etter than $0.5\mu V$ for 30 dB S/N Better than $0.2\mu V$ for 12 dB SINAD More than 12 kHz (-6 dB) Less than 24 kHz (-6 dB)
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance. (-20°C \times +50°C) Spurious radiation	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500!! Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5µV for 30 dB S/N Better than 0 5µV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 60 dB 0.16µV (threshold) Less than 0.2µV (threshold)	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than $\pm 20 \times 10^{-6}$ HI Less than $\pm 20 \times 10^{-6}$ HI Less than -60 dB LOW Less than -53 dB ± 5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch. 500!! Double conversion superheterodyne 1st 1F 10.695 MHz 2nd 1F 455 kHz Better than $0.5\mu V$ for 30 dB S/N Better than $0.5\mu V$ for 12 dB SINAD More than 12 kHz (-6 dB) Less than 24 kHz (-6 dB) Better than 60 dB Better than 60 dB Better than 60 dB Better than 60 dB Better than 60 dB Better than 60 dB Better than 60 dB O $16\mu V$ (threshold)
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance (-20°C \simplified +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity Receiver selectivity Spurious response Squelch sensitivity Auto scan stop level Audio output.	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 - 10 - 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500!! Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0 5µV for 30 dB S/N Better than 0 5µV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 60 dB 0.16µV (threshold) Less than 0.2µV (threshold)	RF output power (at 13.8V DC, 50!! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!) Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0.5µV for 30 dB S/N Better than 0.2µV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 60 dB 0 16µV (threshold) Less than 0.2µV (threshold)
Transmitter Section RF output power (at 13.8V DC, 50\(\Omega\) load) Modulation Frequency tolerance (-20°C \simplified +50°C) Spurious radiation Maximum frequency deviation (FM) Microphone Receiver Section Circuitry Intermediate frequency Receiver sensitivity Receiver selectivity Spurious response Squelch sensitivity Auto scan stop level Audio output.	HI 25 Watts min. LOW 5 Watts approx. (Adjustable) Variable reactance direct shift Less than ±20 · 10 · 6 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz Dynamic microphone with PTT switch, 500Ω Double conversion superheterodyne 1st 1F 10.695 MHz 2nd 1F 455 kHz Better than 0 5ωV for 30 dB S/N Better than 0 5ωV for 30 dB S/N Better than 0 2ωV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 6 dB) Better than 60 dB 0.16ωV (threshold) Less than 0.2ωV (threshold) More than 2.0 watts across	RF output power (at 13.8V DC, 50:! load) Modulation	LOW 5 Watts approx (Adjustable) Variable reactance direct shift Less than ±20 × 10 · 5 HI Less than = 60 dB LOW Less than = 53 dB ±5 kHz 1.750 Hz (Burst): (T) Dynamic microphone with PTT switch, 500!) Double conversion superheterodyne 1st 1F = 10.695 MHz 2nd 1F = 455 kHz Better than 0.5µV for 30 dB S/N Better than 0.2µV for 12 dB SINAD More than 12 kHz (= 6 dB) Less than 24 kHz (= 60 dB) Better than 60 dB 0 16µV (threshold) Less than 0.2µV (threshold)

Note: Circuit and ratings are subject to change without notice due to developments in technology.

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